OPAx323 20MHz High Bandwidth, 114dB CMRR, Low Voltage (1.7V to 5.5V), RRIO Zero-Cross Operational Amplifier

1 Features

- Zero cross amplifier for 1.7V to 5.5V applications
- High rail-to-rail CMRR: 114dB typical
- High gain-bandwidth product: 20MHz
- Fast slew-rate: 33V/µs typical
- Fast 0.01% settling: 200ns typical for 2V step
- Low input offset voltage: ±150µV typical
- Low noise floor: 5.5nV/$\sqrt{Hz}$ typical at 10kHz
- High output current: ±110mA typical I_{SC} at 5.5V
- Quiescent current: 1.6mA/ch typical
- Rail-to-rail input and output
- Unity-gain stable
- Drives up to 150pF without sustained oscillations
- Internal RFI and EMI filtered input pins
- Operating temperature range: –40°C to 125°C

2 Applications

- Amplifier driver for ADCs
- High side current sensing
- Motor rotary encoders
- Transimpedance photodiode amplifiers
- Audio microphone pre-amplifiers
- Ultrasonic transducers

3 Description

The OPAx323 family of op amps includes single (OPA323), dual (OPA2323), and quad-channel (OPA4323), low-voltage (1.7V to 5.5V), high-bandwidth (20MHz) amplifiers (op amps) with a zero-crossover input stage and a rail-to-rail output stage. The zero-crossover input stage enables OPAx323 to achieve high linearity and low distortion for input signals with rail-to-rail swing that are typical in ADC driver applications. Gain-bandwidth of 20MHz provides a fast settling response for ADC sampling speeds between 0.5MSPS to 5MSPS depending on the settling performance required. The OPAx323 is well-optimized for power savings as the device consumes just 1.6mA typical quiescent current.

The OPAx323 easily supports precision performance in high gain voltage sensing applications such as the wheatstone bridge, because of a maximum offset drift of 2µV/°C and thermal noise floor of 5.5nV/rt-Hz with a minimum of 100dB CMRR. This unique combination of higher precision (low offset, drift, noise, distortion, and CMRR) and higher gain-bandwidth (fast settling and slewing) enables use in multiple applications such as the motor rotary encoders, microphone audio pre-amplifiers and ultrasonic transducers.

The OPAx323 achieves a high slew-rate of 33V/µs allowing for fast detection of faults in motor current sensing applications. Unlike traditional amplifiers, the zero-cross over input stage allows for identical precision performance for both low and high-side sensing applications, thus making OPAx323 the best choice for current sensing in a variety of end equipments such as the solar string inverters, power delivery, grid and EV infrastructure. OPAx323S devices provide shutdown functionality for additional power savings and help disable the amplifier when idle. The family features standard and small size as well as leaded and QFN packages across all the channel variants.

Device Information

PART NUMBER[1]	CHANNEL COUNT	PACKAGE[4]	PACKAGE SIZE[5]
OPA323	Single	DBV (SOT-23, 5) [3]	2.9mm × 2.8mm
		DCK (SC70, 5)	2mm × 1.25mm
		DRL (SOT-5X3, 5) [3]	1.6mm × 1.6mm
OPA323S [2]	Single, Shutdown	DBV (SOT-23, 6) [3]	2.9mm × 2.8mm
		DCK (SC70, 6) [3]	2mm × 1.25mm
OPA2323	Dual	D (SOIC, 8)	4.9mm × 6mm
		DDF (SOT-23, 8)	2.9mm × 2.8mm
		DSG (WSON, 8) [3]	2mm × 2mm
		DGK (VSSOP, 8)	3mm × 4.9mm
		PW (TSSOP, 8) [3]	3mm × 6.4mm
OPA2323S [2]	Dual, Shutdown	RUG (X2QFN, 10) [3]	1.5mm × 2mm
OPA4323	Quad	D (SOIC, 14) [3]	8.65mm × 6mm
		PW (TSSOP, 14)	5mm × 6.4mm
		RUC (X2QFN, 14)[3]	2mm × 2mm
		DYY (SOT-23, 14)	4.2mm × 3.26mm
OPA4323S [2]	Quad, Shutdown	RTE (WQFN, 16) [3]	3mm × 3mm

(1) See Section 4.
(2) Part number is for preview only.
(3) Package is for preview only.
(4) For more information, see Section 11.
(5) The package size (length × width) is a nominal value and includes pins, where applicable.
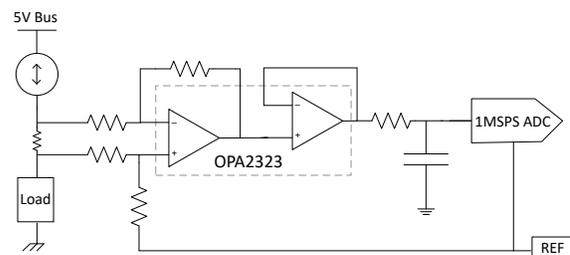
Bidirectional, High-Side Current Sense Amplifier and ADC Driver

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4 Device Comparison Table

| DEVICE	NO. OF CHANNELS	SHDN	PACKAGE LEADS										
			SC70 DCK	SOIC D	SOT-23 DBV[2]	SOT-23 DDF	SOT-553 DRL[2]	SOT-23 DYY	TSSOP PW	VSSOP DGK	WQFN RTE [2]	WSON DSG[2]	X2QFN RUG[2]
OPA323	1	NO	5	—	5	—	5	—	—	—	—	—	—
OPA323S[1]	1	YES	6	—	6	—	—	—	—	—	—	—	—
OPA2323	2	NO	—	8	—	8	—	—	8	8	—	8	—
OPA2323S[1]	2	YES	—	—	—	—	—	—	—	—	—	—	10
OPA4323	4	NO	—	14	—	—	—	14	14	—	—	—	—
OPA4323S	4	YES	—	—	—	—	—	—	—	—	16	—	—

(1)   Devices are preview only.
(2)   Packages are preview only.

5 Pin Configuration and Functions
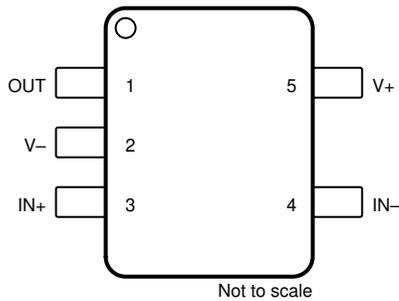
Figure 5-1. OPA323 DBV Package,
5-Pin SOT-23
(Top View)
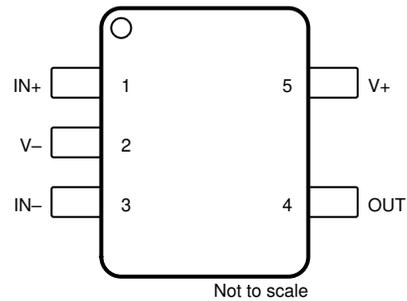
Figure 5-2. OPA323 DCK and DRL Package,
5-Pin SC70 and 5-Pin SOT-5X3
(Top View)

Table 5-1. Pin Functions: OPA323

PIN			TYPE[1]	DESCRIPTION
NAME	SOT-23	SC70, SOT-5X3		
IN–	4	3	I	Inverting input
IN+	3	1	I	Noninverting input
OUT	1	4	O	Output
V–	2	2	I	Negative (low) supply or ground (for single-supply operation)
V+	5	5	I	Positive (high) supply

(1)   I = input, O = output
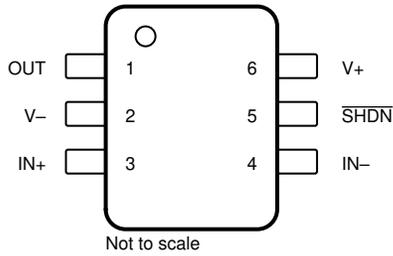
**Figure 5-3. OPA323S DBV Package,
6-Pin SOT-23
(Top View)**
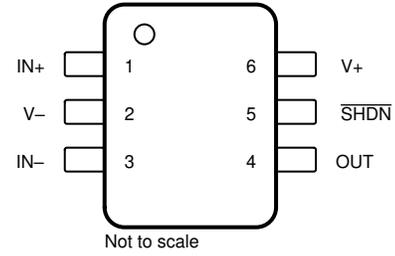
**Figure 5-4. OPA323S DCK Package,
6-Pin SC70
(Top View)**

Table 5-2. Pin Functions: OPA323S

PIN			TYPE[1]	DESCRIPTION
NAME	SOT-23	SC70		
IN–	4	3	I	Inverting input
IN+	3	1	I	Noninverting input
OUT	1	4	O	Output
$\overline{\text{SHDN}}$	5	5	I	Shutdown: low = amp disabled, high = amp enabled See *Shutdown Function* for more information
V–	2	2	I	Negative (low) supply or ground (for single-supply operation)
V+	6	6	I	Positive (high) supply

(1)   I = input, O = output

Product Folder Links: *OPA4323 OPA323 OPA2323*
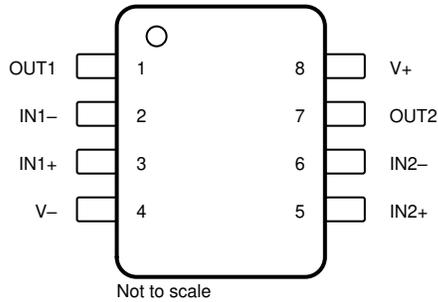
Not to scale

**Figure 5-5. OPA2323 D, PW, DGK, and DDF Package,
SOIC, TSSOP, VSSOP, and SOT-23-THIN
(Top View)**
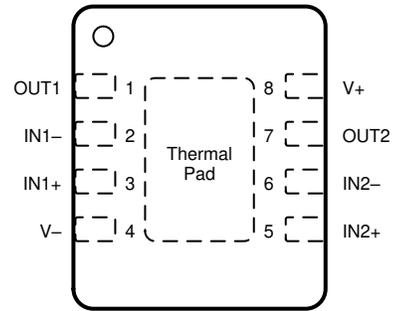
Not to scale

Connect exposed thermal pad to V–. For more information, see
Packages with an Exposed Thermal Pad.

**Figure 5-6. OPA2323 DSG Package,
8-Pin WSON with Exposed Thermal Pad
(Top View)**

Table 5-3. Pin Functions: OPA2323

PIN		TYPE[1]	DESCRIPTION
NAME	SOIC, TSSOP, VSSOP, SOT-23-THIN, WSON		
IN1–	2	I	Inverting input, channel 1
IN1+	3	I	Noninverting input, channel 1
IN2–	6	I	Inverting input, channel 2
IN2+	5	I	Noninverting input, channel 2
OUT1	1	O	Output, channel 1
OUT2	7	O	Output, channel 2
V–	4	I	Negative (low) supply or ground (for single-supply operation)
V+	8	I	Positive (high) supply

(1)   I = input, O = output
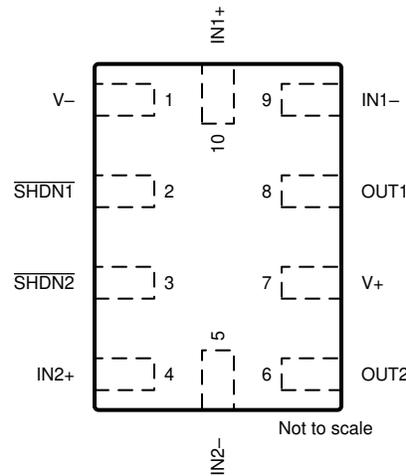
**Figure 5-7. OPA2323S RUG Package
10-Pin X2QFN
(Top View)**

Table 5-4. Pin Functions: OPA2323S

PIN		TYPE[1]	DESCRIPTION
NAME	X2QFN		
IN1–	9	I	Inverting input, channel 1
IN1+	10	I	Noninverting input, channel 1
IN2–	5	I	Inverting input, channel 2
IN2+	4	I	Noninverting input, channel 2
OUT1	8	O	Output, channel 1
OUT2	6	O	Output, channel 2
$\overline{SHDN1}$	2	I	Shutdown: low = amp disabled, high = amp enabled, channel 1. For more information, see *Shutdown Function*.
$\overline{SHDN2}$	3	I	Shutdown: low = amp disabled, high = amp enabled, channel 2. For more information, see *Shutdown Function*.
V–	1	I	Negative (low) supply or ground (for single-supply operation)
V+	7	I	Positive (high) supply

(1)   I = input, O = output

Product Folder Links: *OPA4323 OPA323 OPA2323*
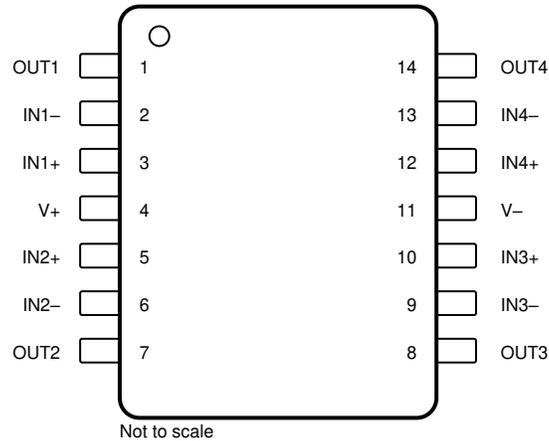
Figure 5-8. OPA4323 D, PW and DYY Package,
14-Pin SOIC, TSSOP, SOT-23-THN
(Top View)

Table 5-5. Pin Functions: OPA4323

PIN		TYPE[1]	DESCRIPTION
NAME	SOIC, TSSOP		
IN1–	2	I	Inverting input, channel 1
IN1+	3	I	Noninverting input, channel 1
IN2–	6	I	Inverting input, channel 2
IN2+	5	I	Noninverting input, channel 2
IN3–	9	I	Inverting input, channel 3
IN3+	10	I	Noninverting input, channel 3
IN4–	13	I	Inverting input, channel 4
IN4+	12	I	Noninverting input, channel 4
OUT1	1	O	Output, channel 1
OUT2	7	O	Output, channel 2
OUT3	8	O	Output, channel 3
OUT4	14	O	Output, channel 4
V–	11	I	Negative (low) supply or ground (for single-supply operation)
V+	4	I	Positive (high) supply

(1)   I = input, O = output
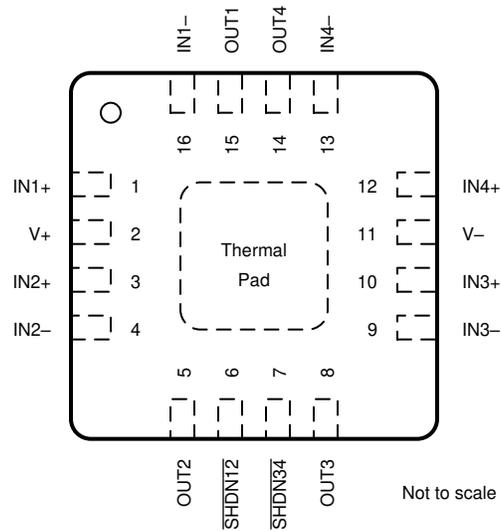
A. Connect thermal pad to V–.

**Figure 5-9. OPA4323S RTE Package,
16-Pin WQFN With Exposed Thermal Pad
(Top View)**

Table 5-6. Pin Functions: OPA4323S

PIN		TYPE[1]	DESCRIPTION
NAME	WQFN		
IN1+	1	I	Noninverting input, channel 1
IN1–	16	I	Inverting input, channel 1
IN2+	3	I	Noninverting input, channel 2
IN2–	4	I	Inverting input, channel 2
IN3+	10	I	Noninverting input, channel 3
IN3–	9	I	Inverting input, channel 3
IN4+	12	I	Noninverting input, channel 4
IN4–	13	I	Inverting input, channel 4
SHDN12	6	I	Shutdown: low = amp disabled, high = amp enabled, channel 1 and 2. For more information, see *Shutdown Function*.
SHDN34	7	I	Shutdown: low = amp disabled, high = amp enabled, channel 3 and 4. For more information, see *Shutdown Function*.
OUT1	15	O	Output, channel 1
OUT2	5	O	Output, channel 2
OUT3	8	O	Output, channel 3
OUT4	14	O	Output, channel 4
V–	11	I	Negative (low) supply or ground (for single-supply operation)
V+	2	I	Positive (high) supply

(1) I = input, O = output

Product Folder Links: *OPA4323 OPA323 OPA2323*

6 Specifications

6.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted) [1]

		MIN	MAX	UNIT
Supply voltage, V_S = (V+) – (V−)	Supply voltage, V_S = (V+) – (V−)	0	7.0	V
Signal input pins	Common-mode voltage [2] [3]	−0.5	6.0	V
	Differential voltage [2] [3]		±6.0	V
	Current [3]	−10	10	mA
Output short-circuit [4]		Continuous		
Operating ambient temperature, T_A		−55	150	°C
Junction temperature, T_J			150	°C
Storage temperature, T_{stg}		−65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods can affect device reliability.
(2) Input pins can swing beyond (V+) but not ±6V. No diode structure from input pins to (V+).
(3) Input pins are diode-clamped to (V−). Input signals that 0.3V below (V−) must be current-limited to 10mA or less.
(4) Short-circuit to ground, one amplifier per package.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 [1]	±4000	V
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 [2] — OPA4323	±500	V
		OPA323, OPA2323	±250	V

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_S	Supply voltage, (V+) – (V−)	1.7	5.5	V
C_{BYP}	Bypass capacitor on the power supply pins [1]	0.1		µF
T_A	Specified temperature	−40	125	°C

(1) For C_{BYP}, use low-ESR ceramic capacitors between each supply pin and ground. Only one C_{BYP} is sufficient for single supply operation. Ensure that C_{BYP} is placed as close to the device as possible and the supply trace routes through C_{BYP} before reaching the supply pin.

6.4 Thermal Information for Single Channel

THERMAL METRIC [1]		OPA323 DCK (SC70) 5 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	196.7	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	104.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	44.8	°C/W
ψ_{JT}	Junction-to-top characterization parameter	18.7	°C/W
ψ_{JB}	Junction-to-board characterization parameter	44.5	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Thermal Information for Dual Channel

THERMAL METRIC [1]		OPA2323			UNIT
		D (SOIC 8 PINS	DGK (VSSOP) 8 PINS	DDF (SOT-23-8) 8 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	139.0	173.6	149.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	81.2	65.1	72.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	82.4	95.1	68.4	°C/W
ψ_{JT}	Junction-to-top characterization parameter	31.3	10.0	4.0	°C/W
ψ_{JB}	Junction-to-board characterization parameter	81.6	93.5	68.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.6 Thermal Information for Quad Channel

THERMAL METRIC [1]		OPA4323 PW (TSSOP) 14 PINS	OPA4323 DYY (SOT) 14 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	115.8	113.7	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	44.9	49.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	58.7	42.4	°C/W
ψ_{JT}	Junction-to-top characterization parameter	5.2	1.6	°C/W
ψ_{JB}	Junction-to-board characterization parameter	58.1	42.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

Product Folder Links: *OPA4323 OPA323 OPA2323*

6.7 Electrical Characteristics

For V_S = (V+) – (V–) = 1.8V to 5.5V (±0.85V to ±2.75V) at T_A = 25°C, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2, unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage	V_S = 1.8V to 5.5V			±0.15	±1.25	mV
		V_S = 1.8V to 5.5V	T_A = –40°C to 125°C			±1.35	
dV_{OS}/dT	Input offset voltage drift [1]	V_S = 1.8V to 5.5V	T_A = –40°C to 125°C		±0.4	±1.8	µV/°C
PSRR	Input offset voltage versus power supply	V_S = 1.8V to 5.5V			±5	±20	µV/V
	Channel separation	f = 10kHz			±1		µV/V
INPUT BIAS CURRENT							
I_B	Input bias current [1]	V_S = 1.8V and V_S = 5V			±0.5	±20	pA
		V_S = 1.8V and V_S = 5V	T_A = –40°C to 125°C			±1600	pA
I_{OS}	Input offset current [1]	V_S = 1.8V and V_S = 5V			±0.25		pA
		V_S = 1.8V and V_S = 5V	T_A = –40°C to 125°C			±120	pA
NOISE							
E_N	Input voltage noise	f = 0.1Hz to 10Hz			2.8		µV$_{PP}$
e_N	Input voltage noise density	f = 100Hz			24		nV/√Hz
		f = 1kHz			9		
		f = 10kHz			5.5		
i_N	Input current noise [2]	f = 1kHz			20		fA/√Hz
INPUT VOLTAGE RANGE							
V_I	Input voltage range	V_S = 1.8V to 5.5V		(V–) – 0.2		(V+) + 0.15	V
CMRR	Common-mode rejection ratio	V_S = 5.5V, (V–) – 0.2V ≤ V_{CM} ≤ (V+) + 0.10V		100	114		dB
		V_S = 5.5V, (V–) – 0.2V ≤ V_{CM} ≤ (V+) + 0.15V		90	104		dB
		V_S = 5.5V, (V–) – 0.2V ≤ V_{CM} ≤ (V+) + 0.15V	T_A = –40°C to 125°C	84			dB
		V_S = 1.8V, (V–) – 0.1V ≤ V_{CM} ≤ (V+) + 0.05V		85	103		dB
		V_S = 1.8V, (V–) – 0.1V ≤ V_{CM} ≤ (V+) + 0.05V	T_A = –40°C to 125°C	80			dB
INPUT IMPEDANCE							
Z_{ID}	Differential				80 || 2		GΩ || pF
Z_{ICM}	Common-mode				100 || 1		GΩ || pF
OPEN-LOOP GAIN							
A_{OL}	Open-loop voltage gain	V_S = 1.8V, (V–) + 0.1V < V_O < (V+) – 0.1V, R_L = 10kΩ to V_S / 2		103	120		dB
		V_S = 1.8V, (V–) + 0.2V < V_O < (V+) – 0.2V, R_L = 2kΩ to V_S / 2		100	115		dB
		V_S = 5.5V, (V–) + 0.1V < V_O < (V+) – 0.1V, R_L = 10kΩ to V_S / 2		112	125		dB
		V_S = 5.5V, (V–) + 0.2V < V_O < (V+) – 0.2V, R_L = 2kΩ to V_S / 2		108	120		dB
FREQUENCY RESPONSE							
GBW	Gain-bandwidth product	V_S = 5.5V, G = +1, R_L = 10kΩ, C_L = 100pF	T_A = 25°C		20		MHz
SR	Slew rate	V_S = 5.5V, G = +1, V_{STEP} = 5V, R_L = 10kΩ, C_L = 100pF			33		V/µs
THD+N	Total harmonic distortion + noise [3]	V_S = 5V, G = +1, V_O = 4V$_{P-P}$, f = 10kHz, R_L = 600Ω to V_S / 2, C_L = 50pF			0.00125		%
t_S	Settling time	To 0.1%, V_S = 5.5V, V_{STEP} = 4V, G = +1, C_L = 10pF			200		ns
		To 0.1%, V_S = 5.5V, V_{STEP} = 2V, G = +1, C_L = 10pF			150		
		To 0.01%, V_S = 5.5V, V_{STEP} = 4V, G = +1, C_L = 10pF			250		
		To 0.01%, V_S = 5.5V, V_{STEP} = 2V, G = +1, C_L = 10pF			200		

6.7 Electrical Characteristics (continued)

For V_S = (V+) – (V–) = 1.8V to 5.5V (±0.85V to ±2.75V) at T_A = 25°C, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and $V_{O\ UT}$ = V_S / 2, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
GM	Gain Margin	V_S = 5.5V, G = +1, R_L = 10kΩ, C_L = 30pF		15		dB
		V_S = 1.8V, G = +1, R_L = 10kΩ, C_L = 30pF		15		dB
PM	Phase Margin	V_S = 5.5V, G = +1, R_L = 10kΩ, C_L = 30pF		50		°
		V_S = 1.8V, G = +1, R_L = 10kΩ, C_L = 30pF		52.5		°
$t_{overload}$	Overload recovery time	V_{IN} × gain > V_S		130		ns
EMIRR	Electro-magnetic interference rejection ratio	f = 1.8GHz, V_{IN_EMIRR} = 100mV		62		dB
OUTPUT						
V_o	Voltage output swing from rail	V_S = 1.8V, R_L = 10kΩ to V_S / 2		15	25	mV
		V_S = 5.5V, R_L = 10kΩ to V_S / 2		25	35	mV
		V_S = 5.5V, R_L = 2kΩ to V_S / 2		45	55	mV
I_{SC}	Short-circuit current [4]	V_S = 1.8V	±20	±40		mA
		V_S = 5.5V	±80	±110		mA
Z_O	Open-loop output impedance	f = 10kHz		80		Ω
POWER SUPPLY						
I_Q	Quiescent current per amplifier	V_S = 5.5V, I_O = 0A		1.6	1.9	mA
		T_A = –40°C to 125°C			2.0	
	Power-on time	V_S = 0V to 5.5V, 90% I_Q Level		25		μs
SHUTDOWN						
I_{QSD}	Shutdown current per amplifier [7]	All amplifiers disabled, $\overline{SHDN}$ = V–		0.5	1	μA
		All amplifiers disabled, $\overline{SHDN}$ = V–, T_A = –40 ℃ to 125 ℃			1.5	μA
Z_{SHDN}	Output impedance during shutdown [7]	Amplifier disabled		43 ‖ 11.5		GΩ ‖ pF
V_{IH}	Logic high threshold voltage (amplifier enabled) [7]		(V–) + 1.15			V
V_{IL}	Logic low threshold voltage (amplifier disabled)				(V–) + 0.20	V
t_{ON}	Amplifier enable time (full shutdown) [5] [6] [7]	G = +1, V_{CM} = V_S / 2, V_O = 0.9 × V_S / 2, R_L connected to V–		8		μs
	Amplifier enable time (partial shutdown) [5] [6] [7]	G = +1, V_{CM} = V_S / 2, V_O = 0.9 × V_S / 2, R_L connected to V–		7.5		
t_{OFF}	Amplifier disable time [5] [7]	G = +1, V_{CM} = V_S / 2, V_O = 0.1 × V_S / 2, R_L connected to V–		1.5		μs
	$\overline{SHDN}$ pin input bias current (per pin) [7]	(V+) ≥ $\overline{SHDN}$ ≥ (V–) + 1V		30		nA
		(V–) ≤ $\overline{SHDN}$ ≤ (V–) + 0.2V		60		

(1)   Max or min limit is specified based on characterization results.
(2)   Typical input current noise data to be specified based on design simulation results
(3)   Third-order filter; bandwidth = 80kHz at –3dB.

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(4)   Short circuit current specified here is average of sourcing and sinking short circuit currents

(5)   Disable time (t_{OFF}) and enable time (t_{ON}) are defined as the time interval between the 50% point of the signal applied to the $\overline{\text{SHDN}}$ pin and the point at which the output voltage reaches the 10% (disable) or 90% (enable) level.

(6)   Full shutdown refers to the dual device having both channels 1 and 2 disabled ($\overline{\text{SHDN1}} = \overline{\text{SHDN2}}$ = V–) and the quad device having all channels 1 to 4 disabled ($\overline{\text{SHDN12}} = \overline{\text{SHDN34}}$ = V–). For partial shutdown, only one $\overline{\text{SHDN}}$ pin is exercised; in this mode, the internal biasing circuitry remains operational and the enable time is shorter.

(7)   Shutdown section is on preview

6.8 Typical Characteristics

at T_A = 25°C, V+ = 2.75V, V− = −2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

V_S = 5.5V V_{CM} = V_S / 2 T_A = 25°C
No. of devices = 36 Mean = −32µV Sigma = 190µV
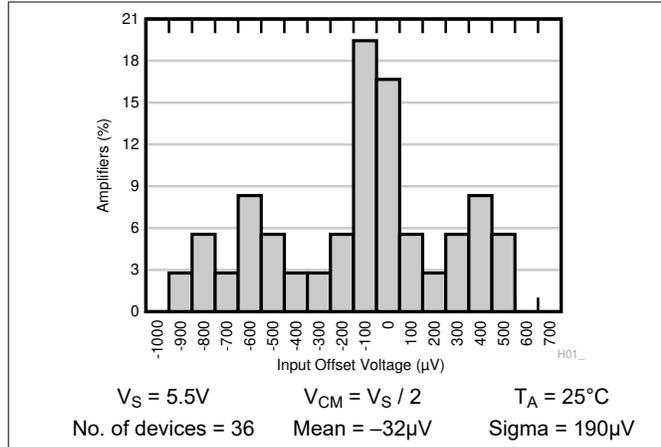
Figure 6-1. Input Offset Voltage Distribution Histogram

V_S = 5.5V V_{CM} = V_S / 2 T_A = −40°C to +125°C
No. of devices = 36
Mean = 0.28µV/°C Sigma = 0.22µV/°C
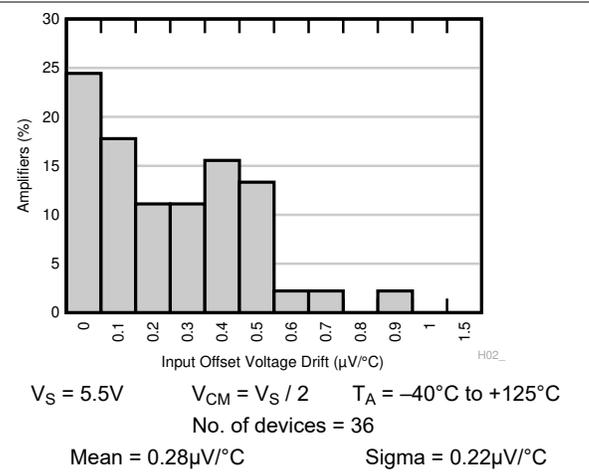
Figure 6-2. Input Offset Voltage Drift Distribution Histogram

V_S = 5.5V V_{CM} = V_S / 2 T_A = 25°C
No. of devices = 90 Mean = 1pA Sigma = 2pA
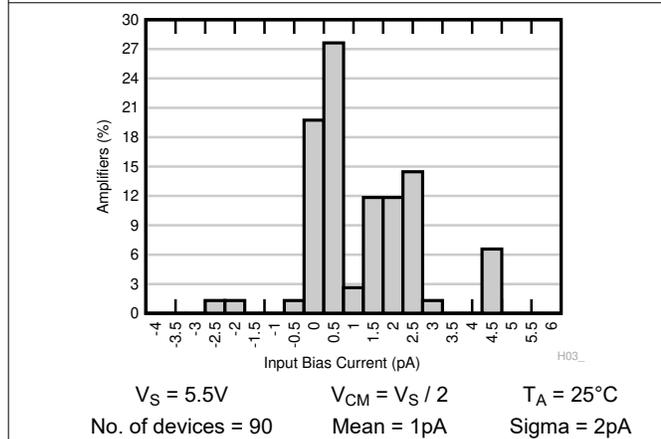
Figure 6-3. Input Bias Current Distribution Histogram

V_S = 5.5V V_{CM} = V_S / 2 T_A = 85°C
No. of devices = 90 Mean = 13pA Sigma = 2pA
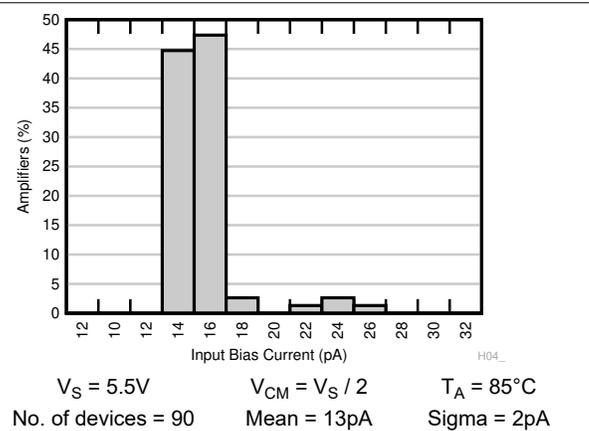
Figure 6-4. Input Bias Current Distribution Histogram

V_S = 5.5V V_{CM} = V_S / 2 T_A = 25°C
No. of devices = 45 Mean = −0.1pA Sigma = 1.7pA
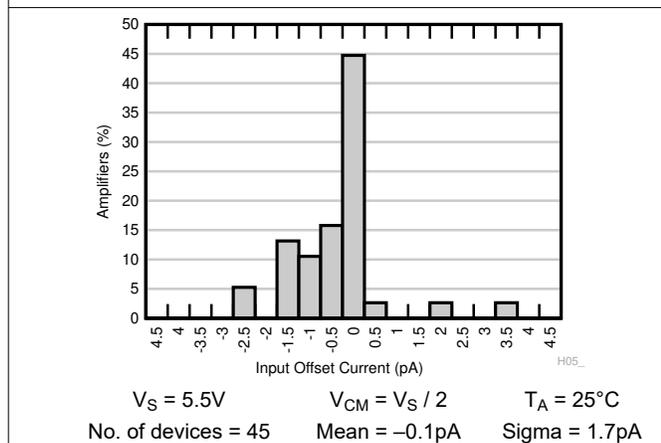
Figure 6-5. Input Offset Current Distribution Histogram

V_S = 5.5V V_{CM} = V_S / 2 T_A = 85°C
No. of devices = 45 Mean = 1.1pA Sigma = 2.1pA
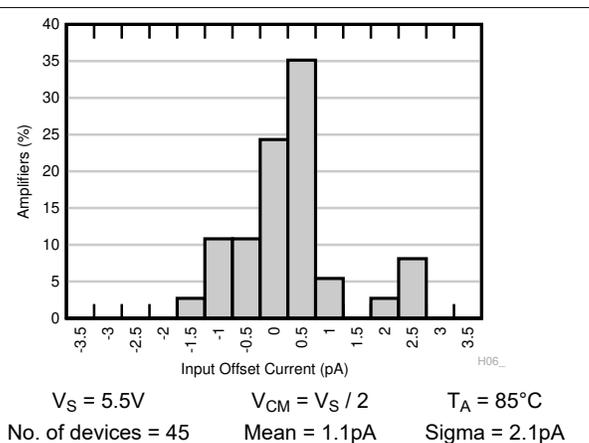
Figure 6-6. Input Offset Current Distribution Histogram

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6.8 Typical Characteristics (continued)

at T_A = 25°C, V+ = 2.75V, V– = –2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

V_{CM} = (V–)   No. of devices = 45
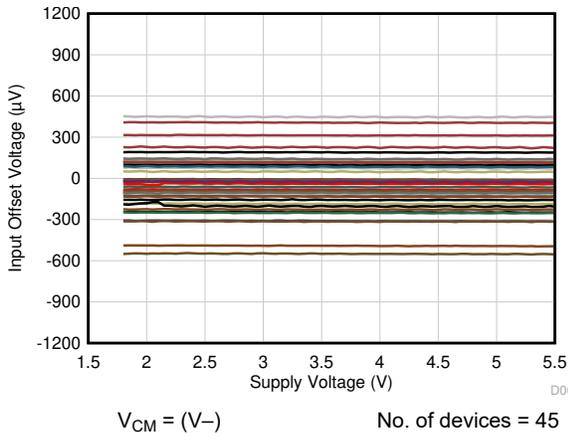
Figure 6-7. Input Offset Voltage vs Supply Voltage

V_{CM} = (V–) T_A = –40°C, 85°C and 125°C
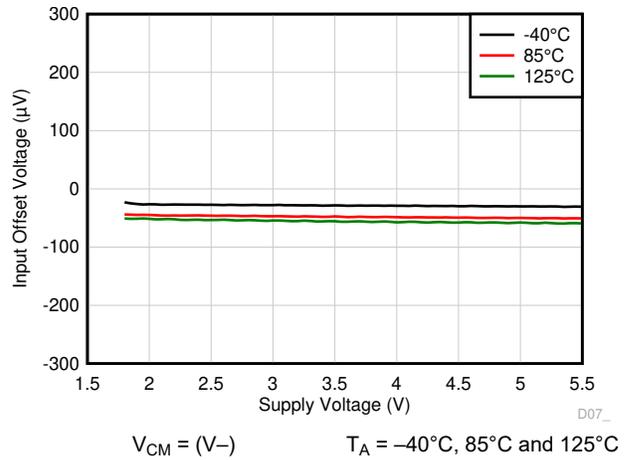
Figure 6-8. Input Offset Voltage vs Supply Voltage

V_{CM} = V–   No. of devices = 45
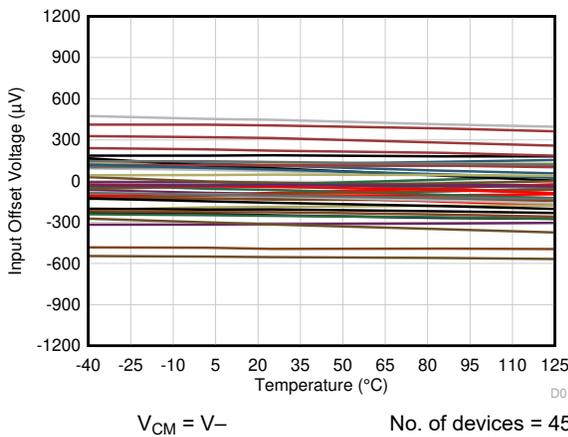
Figure 6-9. Input Offset Voltage vs Temperature

V+ = 2.75V, V– = –2.75V   No. of devices = 45
(V–) – 0.25V < V_{CM} < (V+) + 0.15V
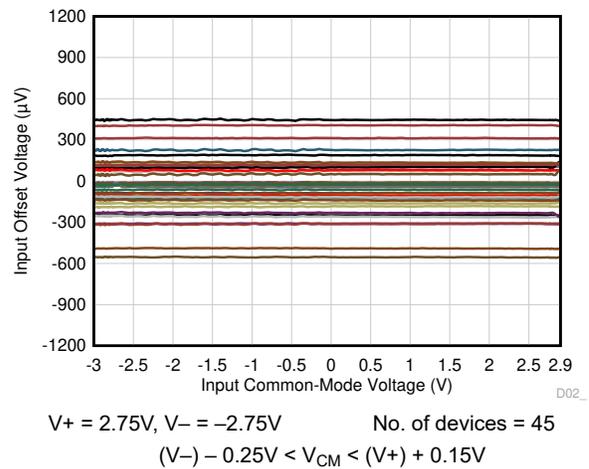
Figure 6-10. Input Offset Voltage vs Common-Mode

V+ = 2.75V, V– = –2.75V T_A = –40°C, 85°C and 125°C
(V–) – 0.25V < V_{CM} < (V+) + 0.15V
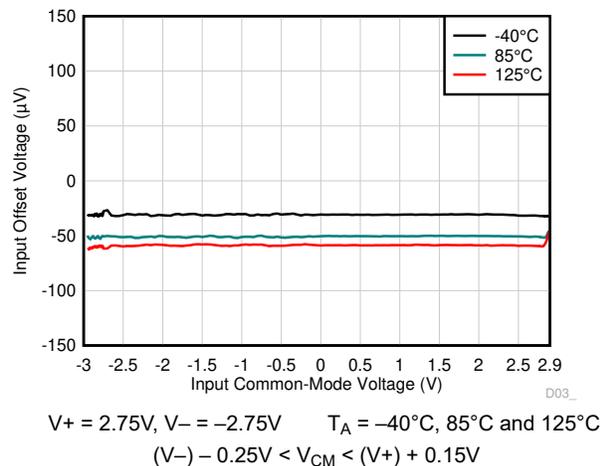
Figure 6-11. Input Offset Voltage vs Common-Mode

V+ = 0.9V, V– = –0.9V   No. of devices = 45
(V–) – 0.1V < V_{CM} < (V+) + 0.1V
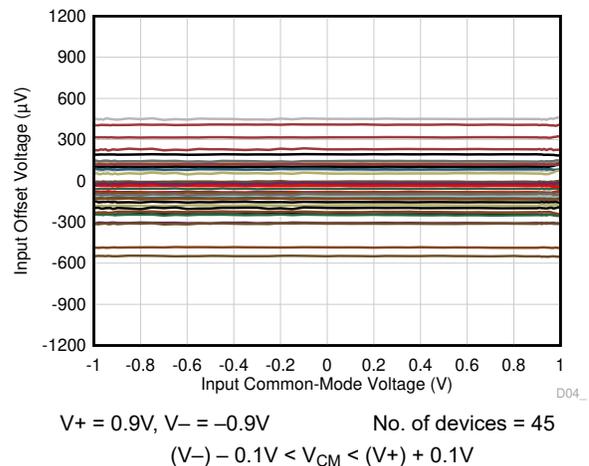
Figure 6-12. Input Offset Voltage vs Common-Mode

6.8 Typical Characteristics (continued)

at T_A = 25°C, V+ = 2.75V, V− = −2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

V+ = 0.9V, V− = −0.9V T_A = −40°C, 85°C and 125°C
(V−) − 0.1V < V_{CM} < (V+) + 0.1V
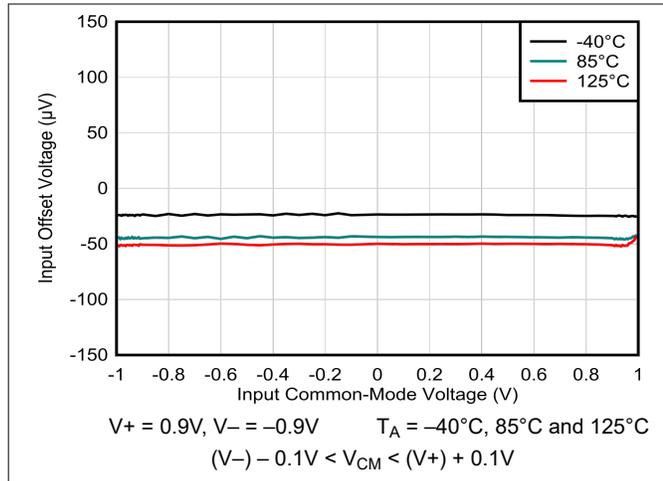
Figure 6-13. Input Offset Voltage vs Common-Mode

V_S = 5.5V, V_{CM} = V_S/2
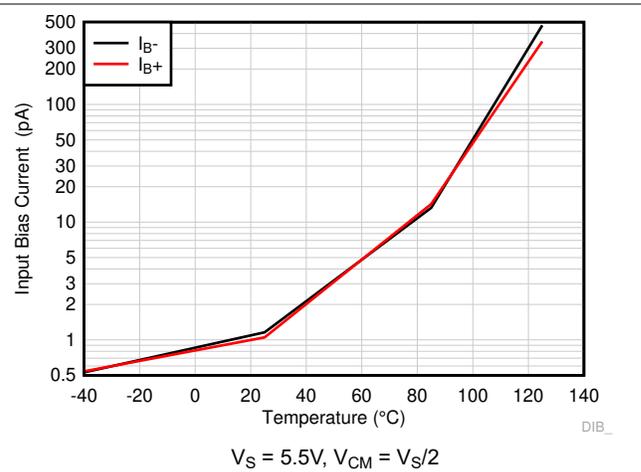
Figure 6-14. I_B vs Temperature

V_S = 5.5V, V_{CM} = V_S/2
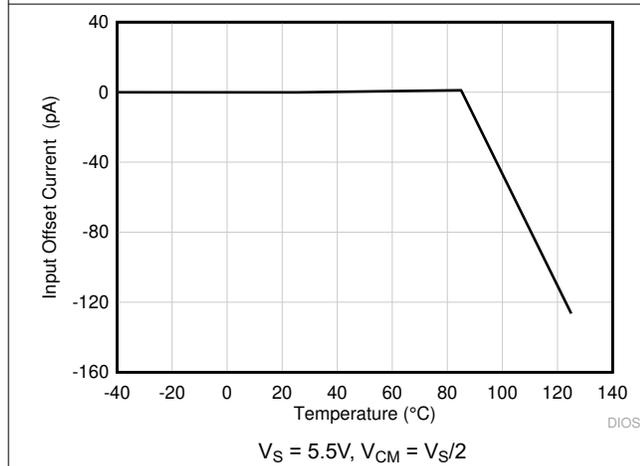
Figure 6-15. I_{OS} vs Temperature

V+ = 2.5V, V− = −2.5V, V_{CM} = V_S/2
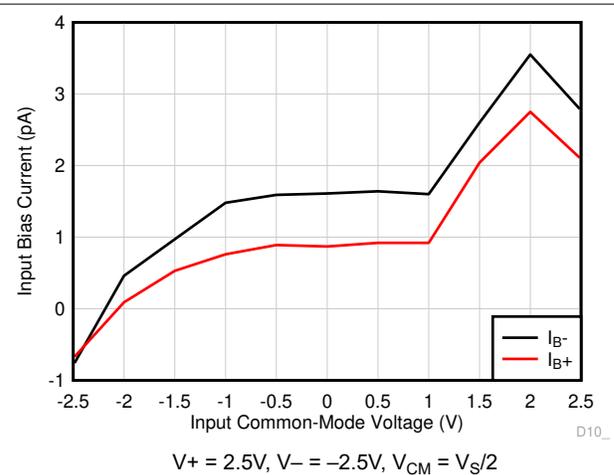
Figure 6-16. I_B vs Common-Mode Voltage

V+ = 2.5V, V− = −2.5V, V_{CM} = V_S/2
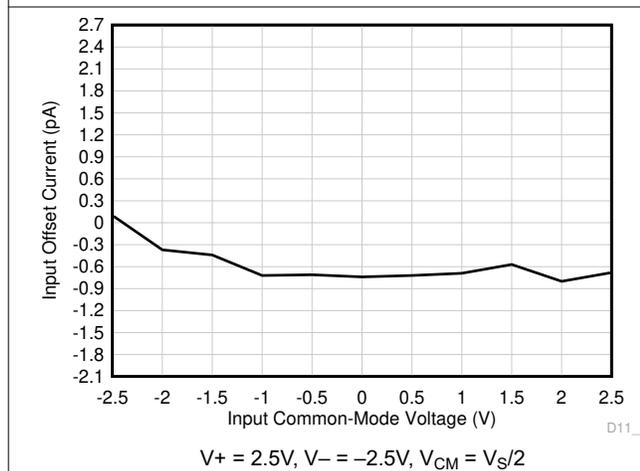
Figure 6-17. I_{OS} vs Common-Mode Voltage
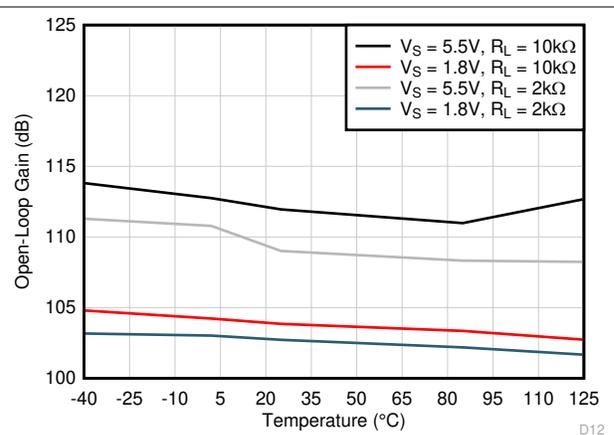
Figure 6-18. Open-Loop Gain vs Temperature

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6.8 Typical Characteristics (continued)

at T_A = 25°C, V+ = 2.75V, V– = –2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

C_L = 10pF
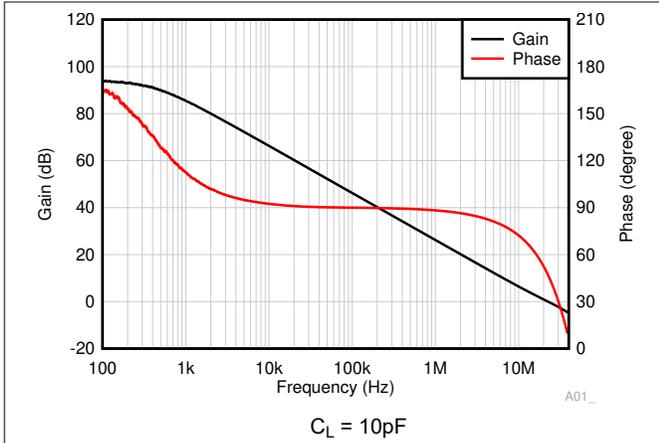
Figure 6-19. Open-Loop Gain and Phase vs Frequency
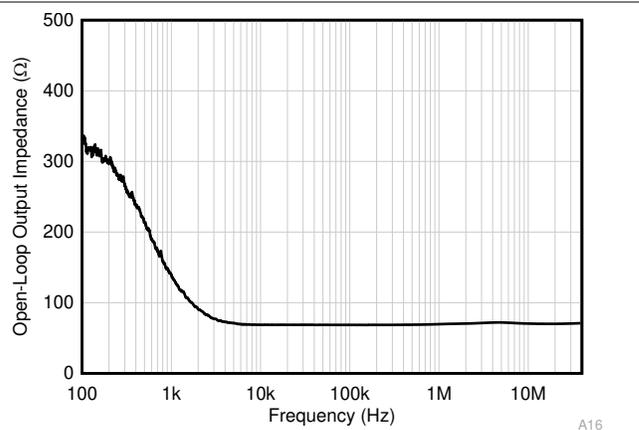
Figure 6-20. Open-Loop Output Impedance vs Frequency

C_L = 10pF
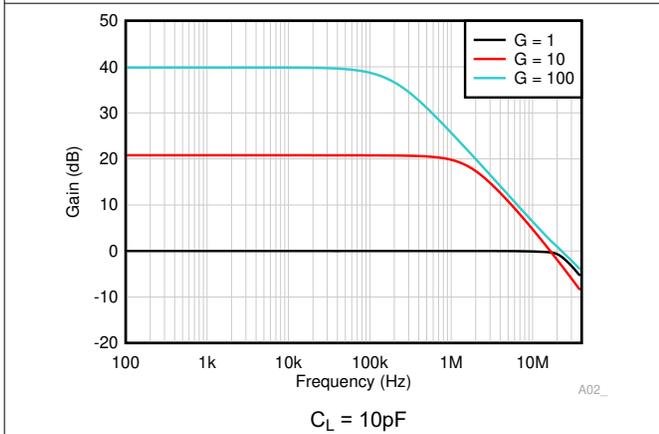
Figure 6-21. Closed-Loop Gain vs Frequency

G = 1000 | C_L = 10pF
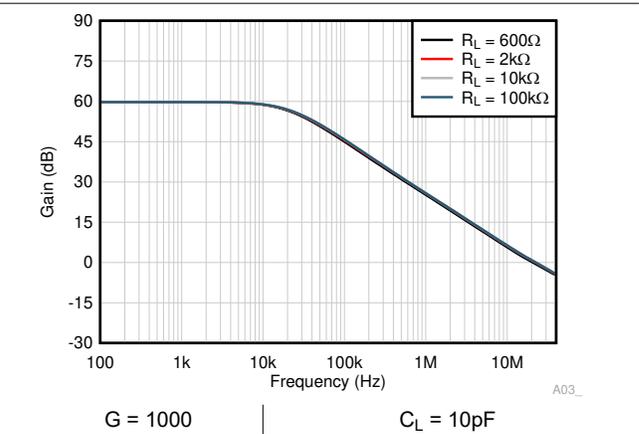
Figure 6-22. Closed-Loop Gain vs Frequency
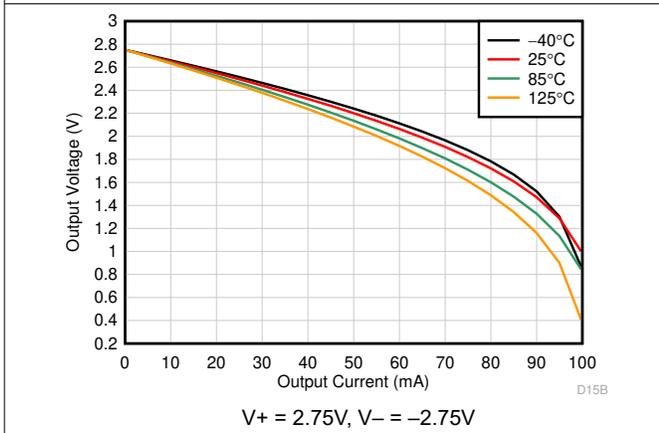
V+ = 2.75V, V– = –2.75V

Figure 6-23. Output Voltage Swing vs Output Current (Sourcing)
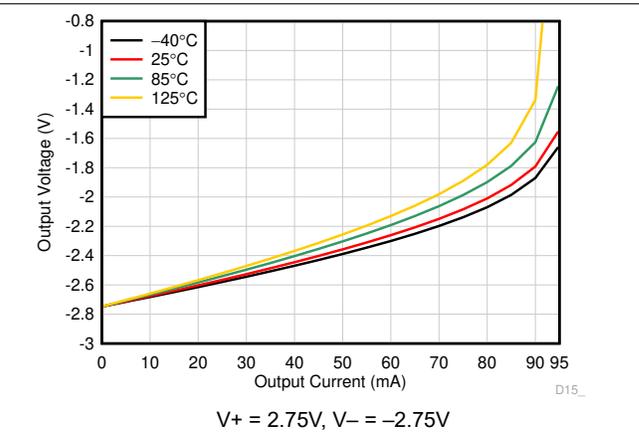
V+ = 2.75V, V– = –2.75V

Figure 6-24. Output Voltage Swing vs Output Current (Sinking)

6.8 Typical Characteristics (continued)

at T_A = 25°C, V+ = 2.75V, V− = −2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

V+ = 1.65V, V− = −1.65V
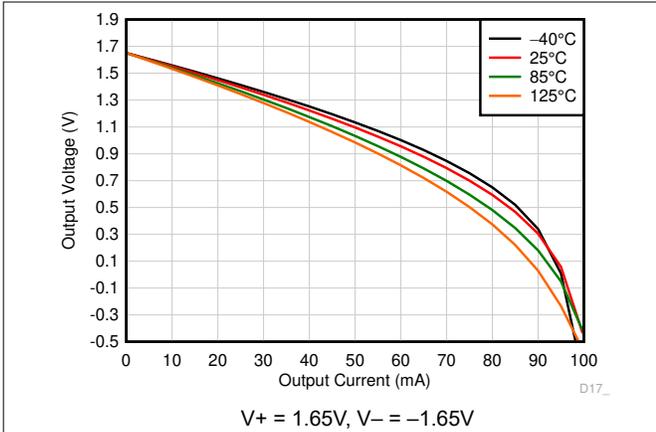
Figure 6-25. Output Voltage Swing vs Output Current (Sourcing)

V+ = 1.65V, V− = −1.65V
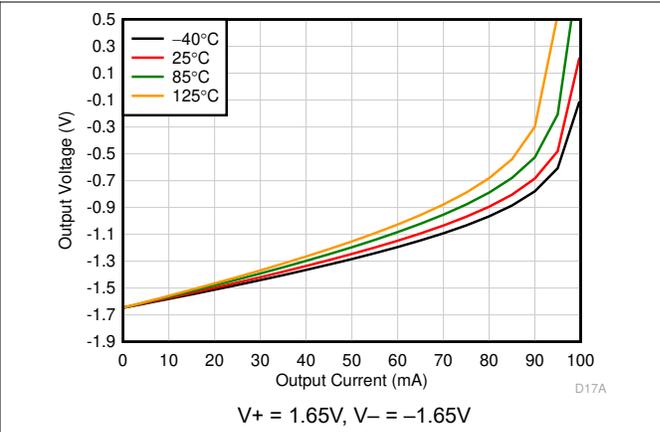
Figure 6-26. Output Voltage Swing vs Output Current (Sinking)

V+ = 0.9V, V− = −0.9V
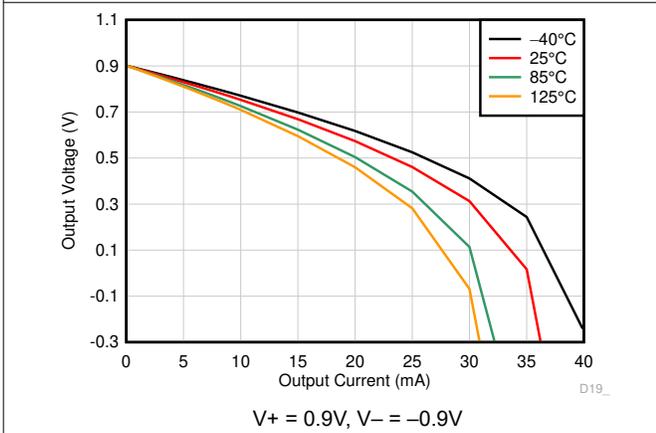
Figure 6-27. Output Voltage Swing vs Output Current (Sourcing)

V+ = 0.9V, V− = −0.9V
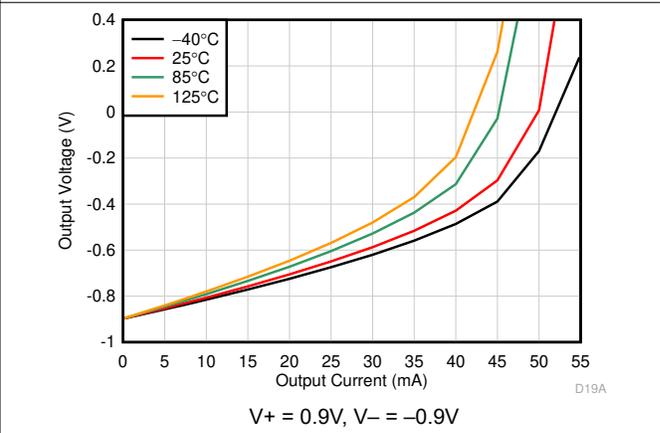
**Figure 6-28. Output Voltage Swing vs Output Current (Sinking)**
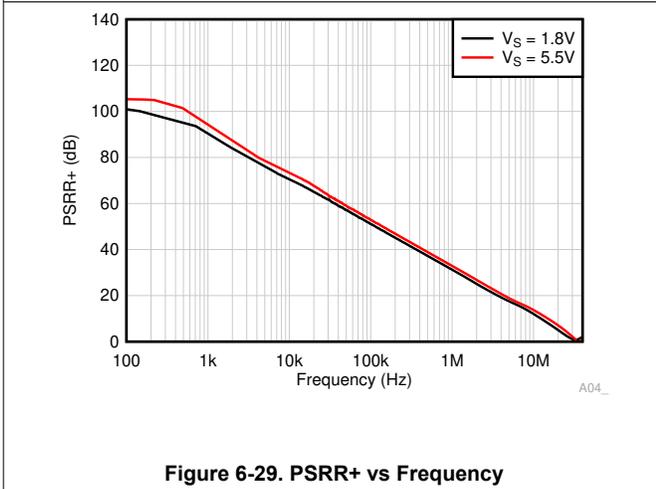
Figure 6-29. PSRR+ vs Frequency
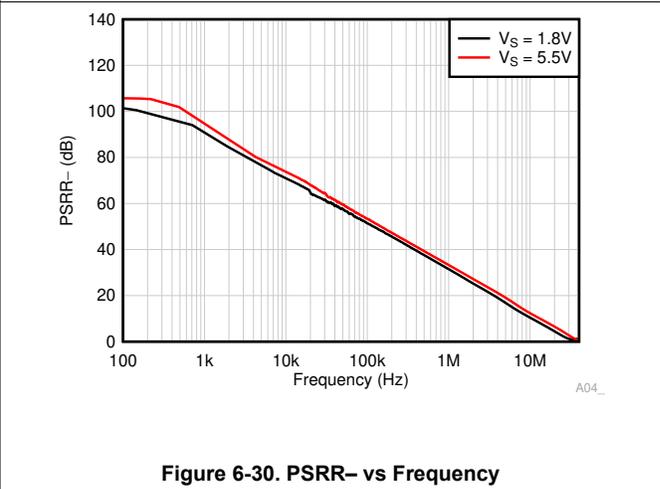
Figure 6-30. PSRR− vs Frequency

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6.8 Typical Characteristics (continued)

at T_A = 25°C, V+ = 2.75V, V– = –2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

V_{CM} = (V–) V_S = 1.8V to 5.5V
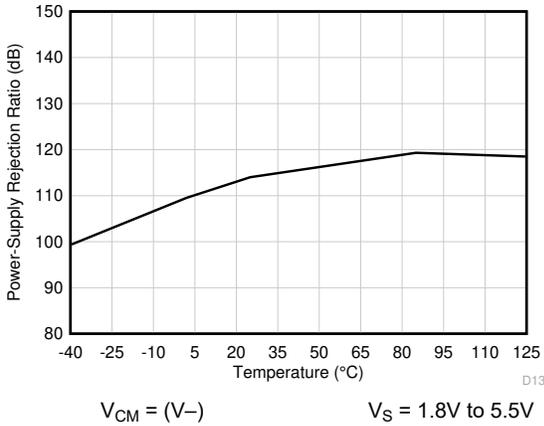
Figure 6-31. DC PSRR vs Temperature
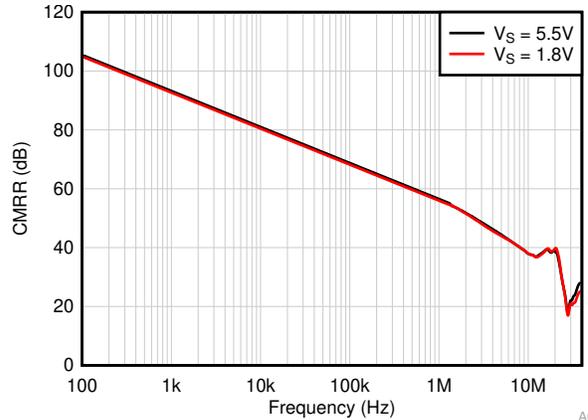
Figure 6-32. CMRR vs Frequency

V_S = 5V   (V–) – 0.2V – < V_{CM} < (V+) + 0.15V
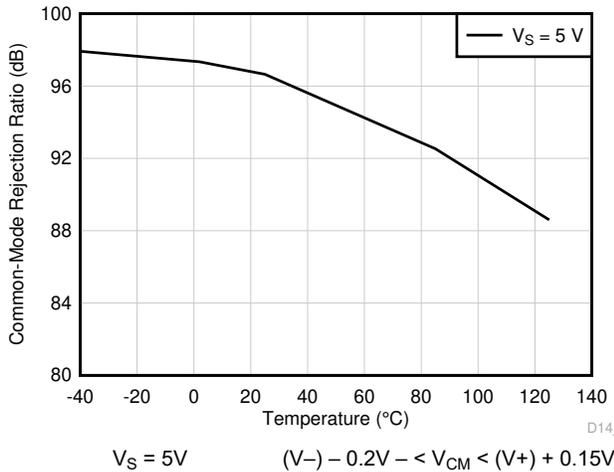
Figure 6-33. DC CMRR vs Temperature
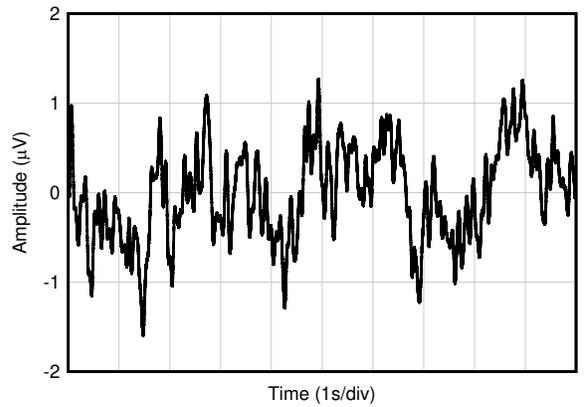
Figure 6-34. 0.1Hz to 10Hz Voltage Noise in Time Domain
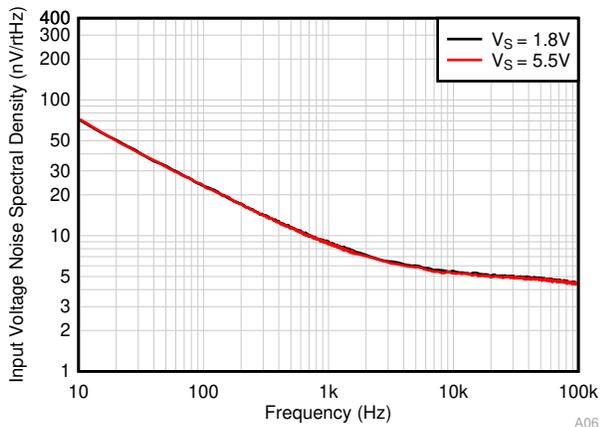
Figure 6-35. Input Voltage Noise Spectral Density
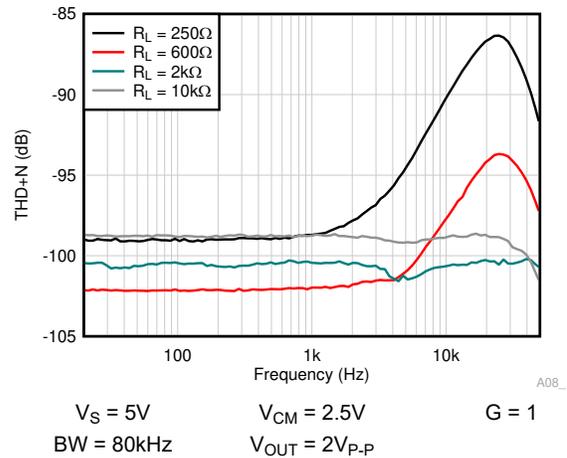

V_S = 5V V_{CM} = 2.5V   G = 1
BW = 80kHz V_{OUT} = 2V_{P-P}

Figure 6-36. THD + N vs Frequency

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6.8 Typical Characteristics (continued)

at T_A = 25°C, V+ = 2.75V, V– = –2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

V_S = 5V V_{CM} = 2.5V   G = –1
BW = 80kHz V_{OUT} = 2V_{P-P}

Figure 6-37. THD + N vs Frequency

V_S = 5V V_{CM} = 2.5V   G = 10
BW = 80kHz V_{OUT} = 2V_{P-P}

Figure 6-38. THD + N vs Frequency

V_S = 5V V_{CM} = 2.5V   G = –10
BW = 80kHz V_{OUT} = 2V_{P-P}

Figure 6-39. THD + N vs Frequency

V_S = 5V V_{CM} = 2.5V   G = 1
BW = 80kHz V_{OUT} = 4V_{P-P}

Figure 6-40. THD + N vs Frequency

V_S = 5V V_{CM} = 2.5V   G = –1
BW = 80kHz V_{OUT} = 4V_{P-P}

Figure 6-41. THD + N vs Frequency

V_S = 5V V_{CM} = 2.5V   G = 10
BW = 80kHz V_{OUT} = 4V_{P-P}

Figure 6-42. THD + N vs Frequency

Product Folder Links: *OPA4323 OPA323 OPA2323*

6.8 Typical Characteristics (continued)

at T_A = 25°C, V+ = 2.75V, V– = –2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

| V_S = 5V | V_{CM} = 2.5V | G = –10 |
| BW = 80kHz | V_{OUT} = 4V_{P-P} | |

Figure 6-43. THD + N vs Frequency

| V_S = 5V | V_{CM} = 2.5V | G = 1 |
| BW = 80kHz | V_{OUT} = 1.4V_{P-P} | |

Figure 6-44. THD + N vs Frequency

| V_S = 5V | V_{CM} = 2.5V | G = –1 |
| BW = 80kHz | V_{OUT} = 1.4V_{P-P} | |

Figure 6-45. THD + N vs Frequency

| V_S = 3.3V | V_{CM} = 1.65V | G = 1 |
| BW = 80kHz | V_{OUT} = 1V_{P-P} | |

Figure 6-46. THD + N vs Frequency

| V_S = 3.3V | V_{CM} = 1.65V | G = –1 |
| BW = 80kHz | V_{OUT} = 1V_{P-P} | |

Figure 6-47. THD + N vs Frequency

| V_S = 5V | V_{CM} = 2.5V | f = 1kHz |
| BW = 80kHz | | |

Figure 6-48. THD + N vs Amplitude

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6.8 Typical Characteristics (continued)

at T_A = 25°C, V+ = 2.75V, V− = –2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

V_S = 3.3V V_{CM} = 1.65V   f = 1kHz
BW = 80kHz

Figure 6-49. THD + N vs Amplitude

V_{CM} = V_S/2
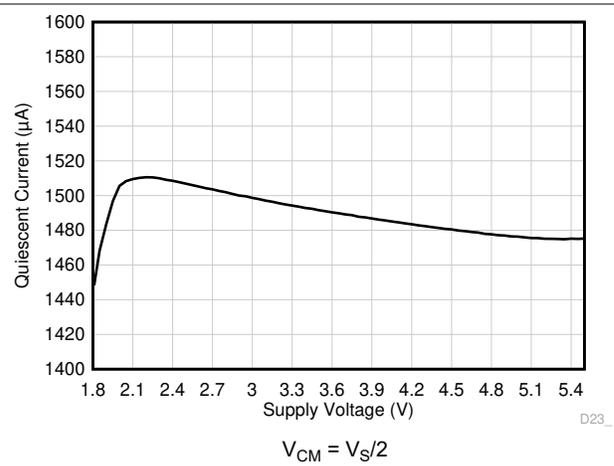
Figure 6-50. Quiescent Current vs Supply Voltage

V+ = 2.75V, V− = –2.75V
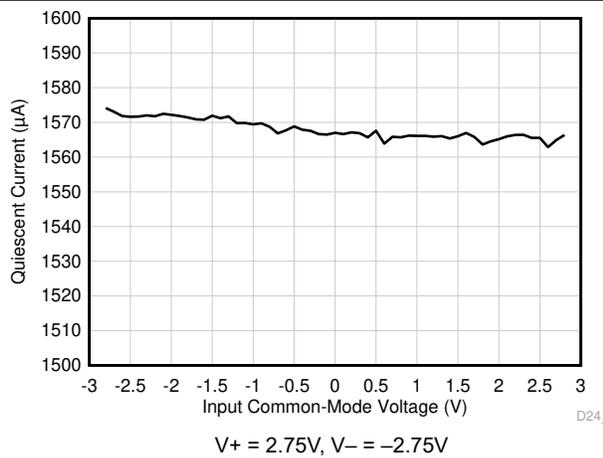
Figure 6-51. Quiescent Current vs Common-Mode Voltage

V_{CM} = V_S/2
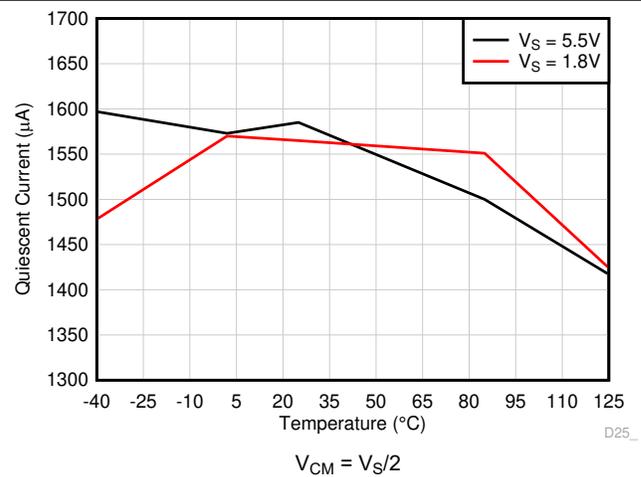
Figure 6-52. Quiescent Current vs Temperature

G = 1 V_{IN} = 100mVpp
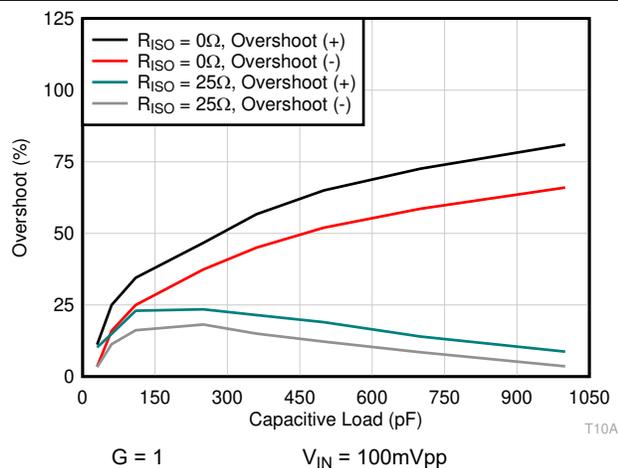
Figure 6-53. Small Signal Overshoot vs Capacitive Load

G = 1 V_{IN} = 100mVpp
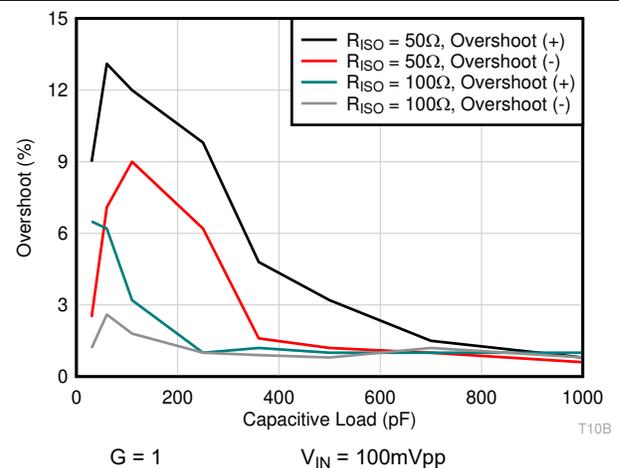
Figure 6-54. Small Signal Overshoot vs Capacitive Load

Product Folder Links: *OPA4323 OPA323 OPA2323*

6.8 Typical Characteristics (continued)

at T_A = 25°C, V+ = 2.75V, V− = −2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)
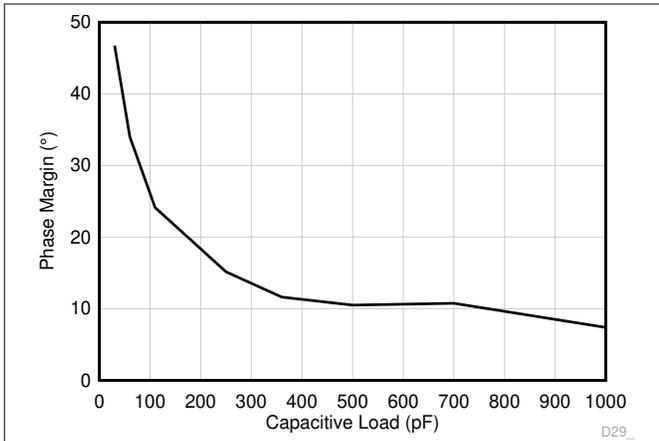
Figure 6-55. Phase Margin vs Capacitive Load
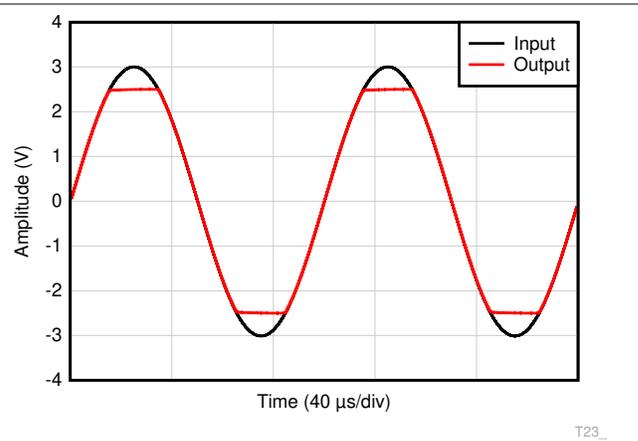
G = 1 V_{IN} = 6V_{PP}

Figure 6-56. No Phase Reversal
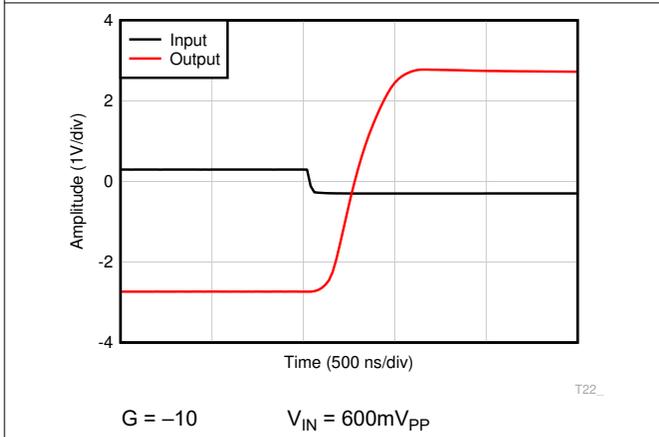
G = −10 V_{IN} = 600mV_{PP}

Figure 6-57. Overload Recovery
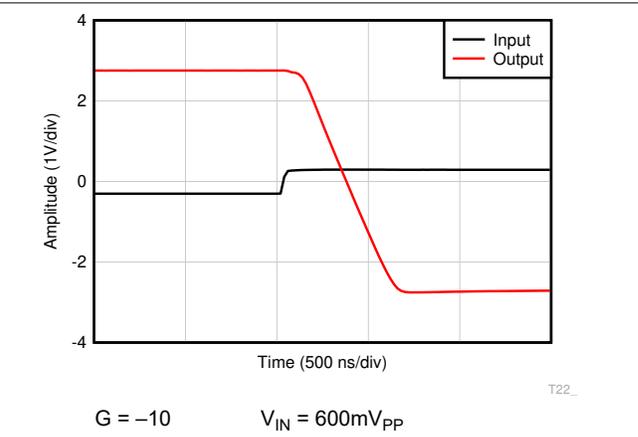
G = −10 V_{IN} = 600mV_{PP}

Figure 6-58. Overload Recovery
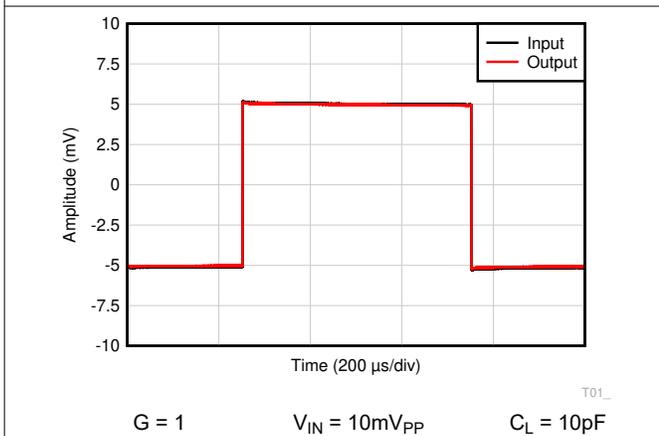
G = 1 V_{IN} = 10mV_{PP} C_L = 10pF

Figure 6-59. Small-Signal Step Response
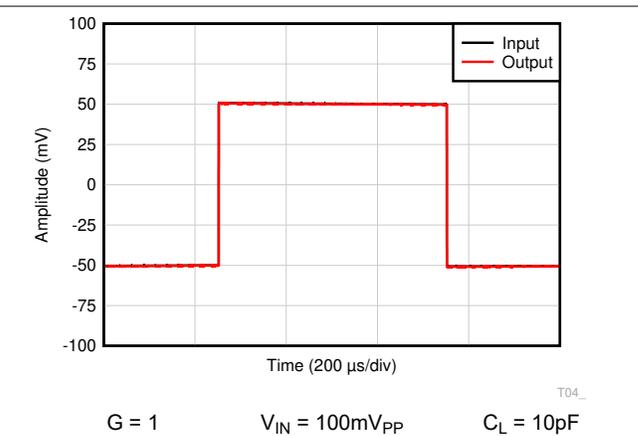
G = 1 V_{IN} = 100mV_{PP} C_L = 10pF

Figure 6-60. Small-Signal Step Response

6.8 Typical Characteristics (continued)

at T_A = 25°C, V+ = 2.75V, V– = –2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

G = –1 V_{IN} = 10mV_{PP} C_L = 10pF
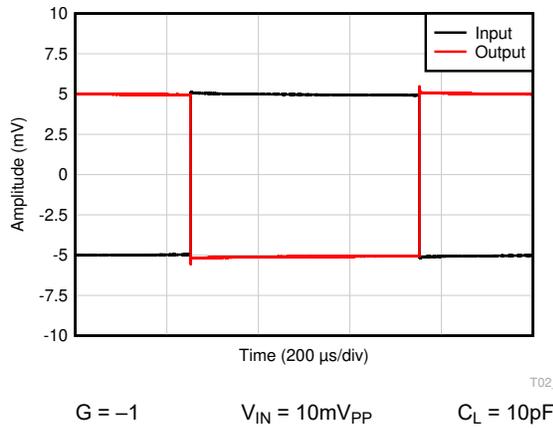
Figure 6-61. Small-Signal Step Response

G = –1 V_{IN} = 100mV_{PP} C_L = 10pF
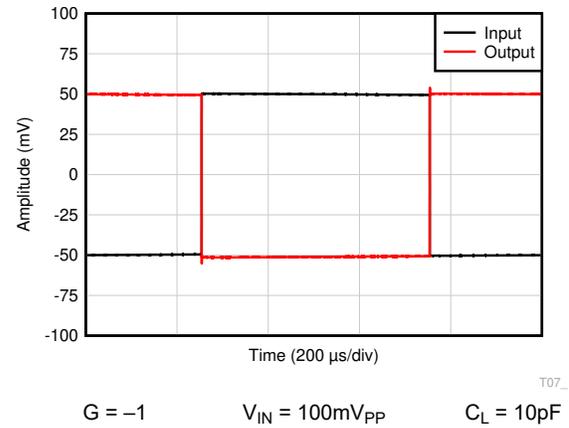
Figure 6-62. Small-Signal Step Response

G = 1 V_{IN} = 4V_{PP} C_L = 10pF
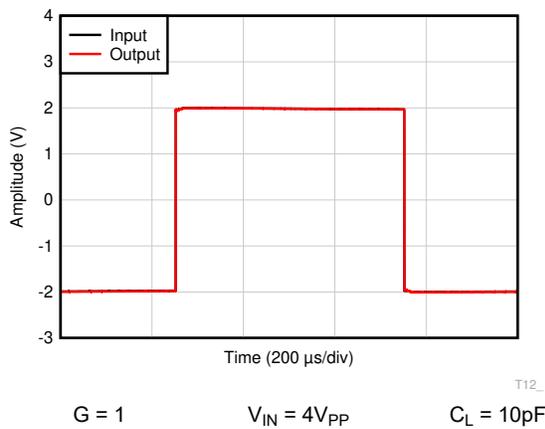
Figure 6-63. Large-Signal Step Response

G = 1 V_{IN} = 2V_{PP} C_L = 10pF
R_L = 2kΩ
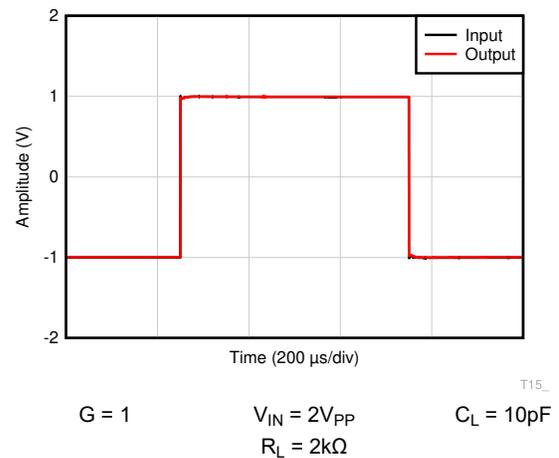
Figure 6-64. Large-Signal Step Response

G = –1 V_{IN} = 4V_{PP} C_L = 10pF
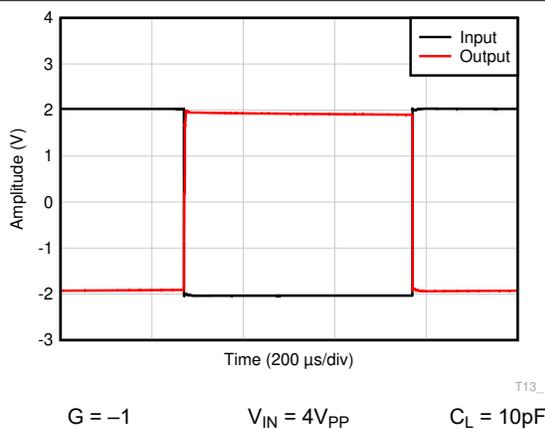
Figure 6-65. Large-Signal Step Response

G = –1 V_{IN} = 2V_{PP} C_L = 10pF
R_L = 2kΩ
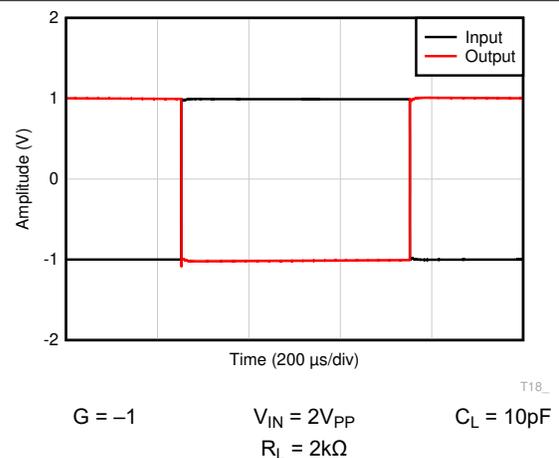
Figure 6-66. Large-Signal Step Response

Product Folder Links: *OPA4323 OPA323 OPA2323*

6.8 Typical Characteristics (continued)

at T_A = 25°C, V+ = 2.75V, V– = –2.75V, R_L = 10kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

V_S = 5.5V

Figure 6-67. Short-Circuit Current vs Temperature

V_S = 1.8V
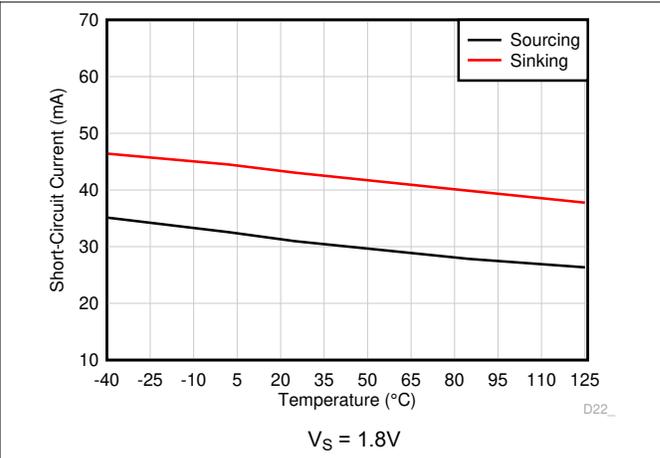
Figure 6-68. Short-Circuit Current vs Temperature
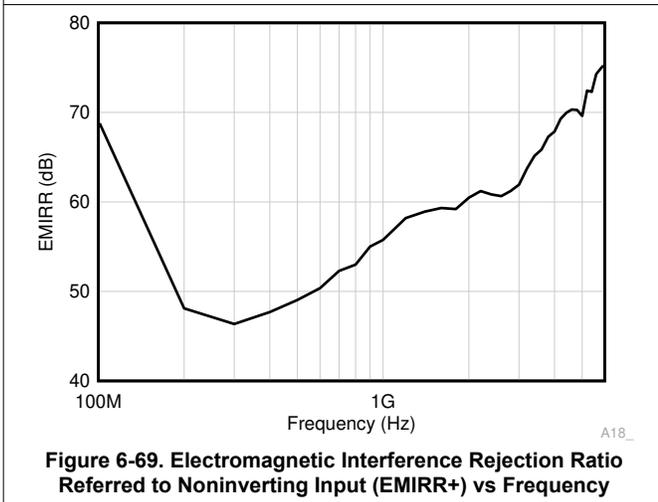
Figure 6-69. Electromagnetic Interference Rejection Ratio Referred to Noninverting Input (EMIRR+) vs Frequency
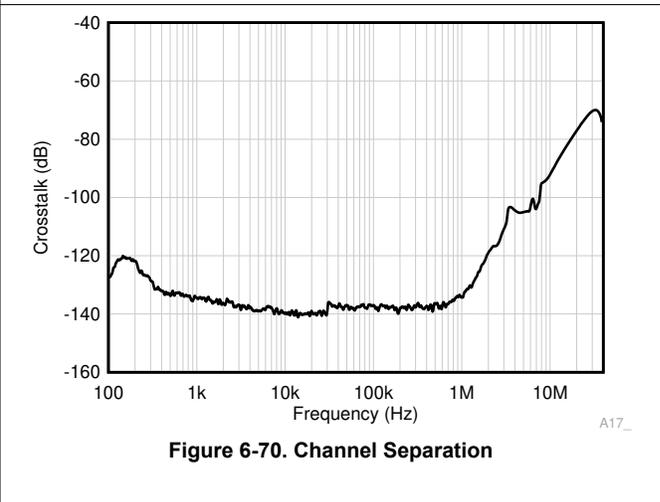
Figure 6-70. Channel Separation

7 Detailed Description

7.1 Overview

The OPAx323 family of op amps includes single / dual / quad channel (OPA323, OPA2323, OPA4323), ultra low-voltage (1.7V to 5.5V), high-bandwidth (20MHz) amplifiers. This family of amplifiers feature a zero-crossover input stage and a rail-to-rail output stage that can be used for variety of applications across industrial and automotive markets. The input common-mode voltage range includes signal swing beyond the supply rails, and allows the OPAx323 to be used in many single-supply or dual supply configurations. Rail-to-rail output swing significantly increases dynamic range, especially in low-supply applications with the class AB output stage capable of driving smaller resistive loads.

The OPAx323 family of zero-cross input stage amplifiers achieve high linearity for input signals with rail-to-rail swing that are typical in ADC driver applications in comparison to the complementary input stage amplifiers. Gain-bandwidth of 20MHz helps provide a fast settling response for ADC sampling speeds between 0.5 to 5MSPS depending on the settling performance required. The OPAx323 easily supports precision performance in high gain voltage sensing applications (such as the wheatsone bridge), as the device features maximum offset of 1.25mV and drift of 1.8µV/°C. This unique combination of high precision and high gain-bandwidth enables use in multiple applications such as the motor rotary encoders, microphone audio pre-amplifiers and ultrasonic transducers.

The OPAx323 family consumes only 1.6mA supply current per channel for 20MHz gain bandwidth, thus providing a good AC performance at a very low power consumption. These devices achieve a high slew-rate of 33V/µs allowing for fast detection of faults in motor current sensing applications. The zero-cross over input stage provides identical AC and DC performance for both low and high-side sensing applications, thus making the OPAx323 the best choice for current sensing in a variety of end equipments such as the solar string inverters, power delivery, grid, and EV infrastructure. Precision transimpedance and voltage gain applications are well served with a low input bias current (0.5pA typical, 20pA maximum), a good PSRR (20µV/V maximum), CMRR (100dB minimum), and A_{OL} (114dB minimum). The device has 60° of typical phase margin with no load and drives up to 75pF with a phase margin of 35°.

The OPAx323 has an internal current limit that enables additional robustness when operating with high output current while driving smaller output impedance like 68Ω, 128Ω, and 256Ω loads in audio applications. The OPAx323 can swing very close to the rails and has a short circuit current of ±80mA minimum at 5.5V power supply. The OPAx323S devices provide shutdown functionality for additional power savings and help disable the amplifier when idle. These op amps feature an integrated radio frequency immunity (RFI) and electro-magnetic interference (EMI) rejection filter, unity-gain stability, and no-phase reversal in input overdrive conditions.

Product Folder Links: *OPA4323 OPA323 OPA2323*

7.2 Functional Block Diagram

Product Folder Links: *OPA4323 OPA323 OPA2323*
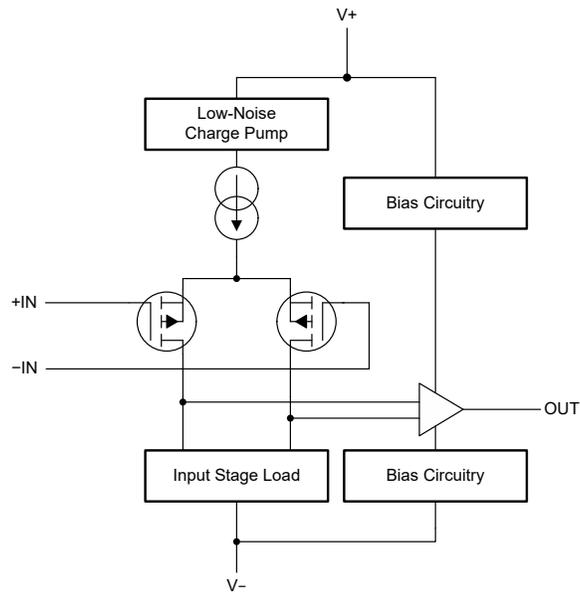
7.3 Feature Description

7.3.1 Operating Voltage

The OPAx323 series of operational amplifiers is fully specified from 1.8V to 5.5V and is designed for amplifier operation from 1.7V to 1.8V. In addition, many specifications apply from –40°C to 125°C. Parameters that vary significantly with operating voltages or temperature are provided in the *Typical Characteristics* section. TI highly recommends to add low-ESR ceramic bypass capacitors (C_{BYP}) between each supply pin and ground. Only one C_{BYP} is sufficient for single supply operation. Make sure that C_{BYP} is placed as close to the device as possible and the power supply trace routes through C_{BYP} before reaching the amplifier power supply terminals.

7.3.2 Rail-to-Rail Input

The input common-mode voltage range of the OPAx323 series extends beyond the supply rails with a common-mode rejection ratio (CMRR) of 100dB minimum at 5.5V as specified in *Electrical Characteristics*. The device is designed to have a good performance of 85dB minimum CMRR even when operating at an ultra-low supply voltage of 1.8V. This is made possible by using a zero-cross input stage architecture for the amplifier input pair.

Most commercial amplifiers employ a complementary input stage architecture which often limits the rail-to-rail CMRR to less than 65dB. This is because the offset performance across the rail-to-rail input common-mode range is not linear. One of the input pairs, usually, the P-channel pair with better offset, noise performance is designed to cover the majority of the common-mode range with the N-channel pair slated to slowly take over at a certain threshold voltage from the positive rail. The creates a big jump in the offset voltage across common mode when transitioning across the input pairs as shown in TLV900x Offset Voltage vs Common-Mode. This offset jump not only affects CMRR but also limits linearity / THD for rail-to-rail input signals.

The OPAx323 achieves linear offset performance over the entire rail-to-rail input range by extending the common-mode-range of a single P-channel input pair using an internal charge pump as shown in the *Functional Block Diagram*. This eliminates the need for the N-channel input pair and the resulting offset jump caused by input pair transitions.

The OPAx323 exhibits near to zero shift in offset voltage across the entire common-mode voltage as shown in Figure 7-1. This is crucial to achieving high linearity in ADC driver and audio driver applications.

V+ = 2.75V, V– = –2.75V   No. of devices = 45

(V–) – 0.25V < V_{CM} < (V+) + 0.15V
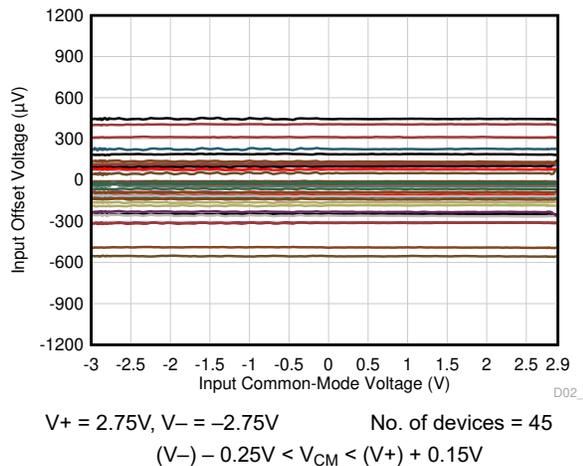
Figure 7-1. OPAx323 Offset Voltage vs Common-Mode

V+ = 2.75V, V– = –2.75V
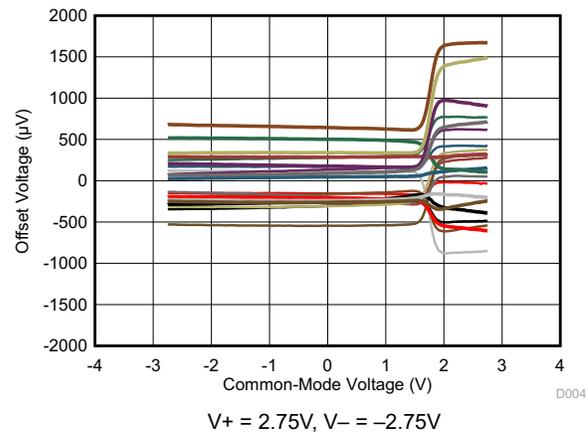
Figure 7-2. TLV900x Offset Voltage vs Common-Mode

7.3.3 Rail-to-Rail Output

The OPAx323 delivers a robust output drive capability. An output stage with common-source transistors is used to achieve full rail-to-rail output swing capability. The device is designed to have a minimum output short circuit current of ±80mA, making the device an excellent choice for audio driver applications at room temperature and

Product Folder Links: *OPA4323 OPA323 OPA2323*

at 5.5V. For resistive loads up to 2kΩ and a power supply of 5.5V, the output swings within a maximum of 55mV to either supply rail, thereby using almost the entire input range of an ADC in ADC driver applications.

7.3.4 Common-Mode Rejection Ratio (CMRR)

The OPAx323 achieves excellent DC and AC CMRR performance. The device is designed to have a DC CMRR performance at two supply voltages (5.5V and 1.8V) for the entire operating temperature range (–40°C to 125°C). DC CMRR is specified for common-mode beyond rails over a input voltage range of $(V-) - 0.2V \leq V_{CM} \leq (V+) + 0.15V$ for 5.5V operation and $(V-) - 0.1V \leq V_{CM} \leq (V+) + 0.05V$ for 1.8V operation. AC CMRR is shown in *Typical Characteristics* and is subject to the routing of input traces on the PCB board. For good performance, maintain a short and symmetrical input trace for the two amplifier input terminals.

7.3.5 Capacitive Load and Stability

The OPAx323 is designed for use in applications where driving a capacitive load is required. As with all operational amplifiers, there can be specific instances where the device can become unstable. The particular operational amplifier circuit configuration, layout, gain, and output loading are some of the factors to consider when establishing whether or not an amplifier is stable in operation.

An operational amplifier in the unity-gain (1V/V) buffer configuration that drives a capacitive load exhibits a greater tendency to be unstable than an amplifier operating at a higher noise gain. The capacitive load, in conjunction with the operational amplifier output resistance, creates a pole within the feedback loop that degrades the phase margin. The degradation of the phase margin increases when capacitive loading increases. When operating in the unity-gain configuration, the OPAx323 has a phase margin of 50° with 30pF of capacitive load. The device remains stable with pure capacitive loads up to approximately 75pF with acceptable phase margin of 35° and has no sustained oscillations up to 150pF. The equivalent series resistance (ESR) of some very large capacitors (greater than 1μF) is sometimes sufficient to alter the phase characteristics in the feedback loop such that the amplifier remains stable. Increasing the amplifier closed-loop gain allows the amplifier to drive increasingly larger capacitance. This increased capability is evident when measuring the overshoot response of the amplifier at higher voltage gains.

One technique for increasing the capacitive load drive capability of the amplifier operating in a unity-gain configuration is to insert a small resistor (typically 10Ω to 50Ω) in series with the output, as shown in Figure 7-3. This resistor significantly reduces the overshoot and ringing associated with large capacitive loads. This is usually the circuit configuration used in ADC driver application with C_{load} serving as a charge bucket for the ADC sampling capacitor.
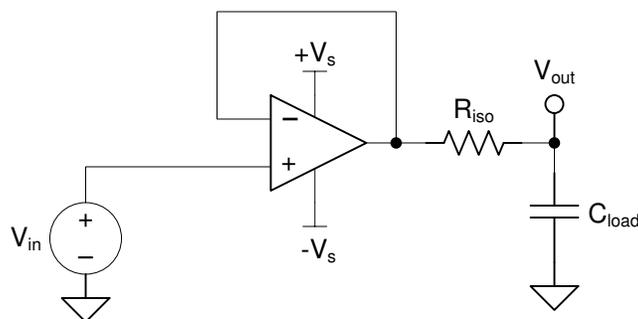
Figure 7-3. Improving Capacitive Load Drive

7.3.6 Overload Recovery

Overload recovery is defined as the time required for the operational amplifier output to recover from a saturated state to a linear state. The output stage of the operational amplifier enters a saturation region when the output voltage exceeds the rated operating voltage, because of the high input voltage or high gain. After one of the outputs enters the saturation region, the output stage requires additional time to return to the linear operating state which is referred to as overload recovery time. After the output stage returns to linear operating state, the

amplifier begins to slew at the specified slew rate. Therefore, the propagation delay (in case of an overload condition) is the sum of the overload recovery time and the slew time.

The overload recovery time for the OPAx323 family is designed to be approximately 130ns typical.

7.3.7 EMI Rejection

The OPAx323 uses integrated electromagnetic interference (EMI) filtering to reduce the effects of EMI from sources such as wireless communications (radio frequency interference - RFI) and densely-populated boards with a mix of analog signal chain and digital components. EMI immunity can be improved with circuit design techniques; the OPAx323 benefits from these design improvements. Texas Instruments has developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10MHz to 6GHz. Figure 7-4 shows the results of this testing on the OPAx323. Table 7-1 shows the EMIRR IN+ values for the OPAx323 at particular frequencies commonly encountered in real-world applications. The *EMI Rejection Ratio of Operational Amplifiers* application report contains detailed information on the topic of EMIRR performance relating to op amps.

Figure 7-4. EMIRR Testing

Product Folder Links: *OPA4323 OPA323 OPA2323*
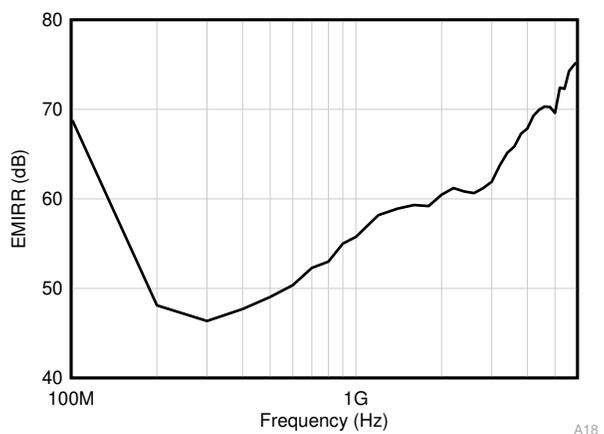
Table 7-1. OPAx323 EMIRR IN+ for Frequencies of Interest

FREQUENCY	APPLICATION OR ALLOCATION	EMIRR IN+
400MHz	Mobile radio, mobile satellite, space operation, weather, radar, ultra-high frequency (UHF) applications	48dB
900MHz	Global system for mobile communications (GSM) applications, radio communication, navigation, GPS (to 1.6GHz), GSM, aeronautical mobile, UHF applications	56dB
1.8GHz	GSM applications, mobile personal communications, broadband, satellite, L-band (1GHz to 2GHz)	60dB
2.4GHz	802.11b, 802.11g, 802.11n, Bluetooth®, mobile personal communications, industrial, scientific and medical (ISM) radio band, amateur radio and satellite, S-band (2GHz to 4GHz)	61dB
3.6GHz	Radiolocation, aero communication and navigation, satellite, mobile, S-band	67dB
5GHz	802.11a, 802.11n, aero communication and navigation, mobile communication, space and satellite operation, C-band (4GHz to 8GHz)	70dB

7.3.8 ESD and Electrical Overstress

Designers often ask questions about the capability of an operational amplifier to withstand electrical overstress. These questions tend to focus on the device inputs, but can involve the supply voltage pins or even the output pin. Each of these different pin functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the pin. Additionally, internal electrostatic discharge (ESD) protection is built into these circuits to protect them from accidental ESD events both before and during product assembly.

Having a good understanding of this basic ESD circuitry and relevance to an electrical overstress event is helpful. Figure 7-5 shows the ESD circuits contained in the OPAx323 devices. The ESD protection circuitry involves several current-steering diodes connected from the input and output pins and routed back to the internal power supply lines, where the input and output pins meet at an absorption device internal to the operational amplifier. This protection circuitry is intended to remain inactive during normal circuit operation.

Note that the OPAx323 features no current-steering diodes connected between the input and positive power-supply pin.
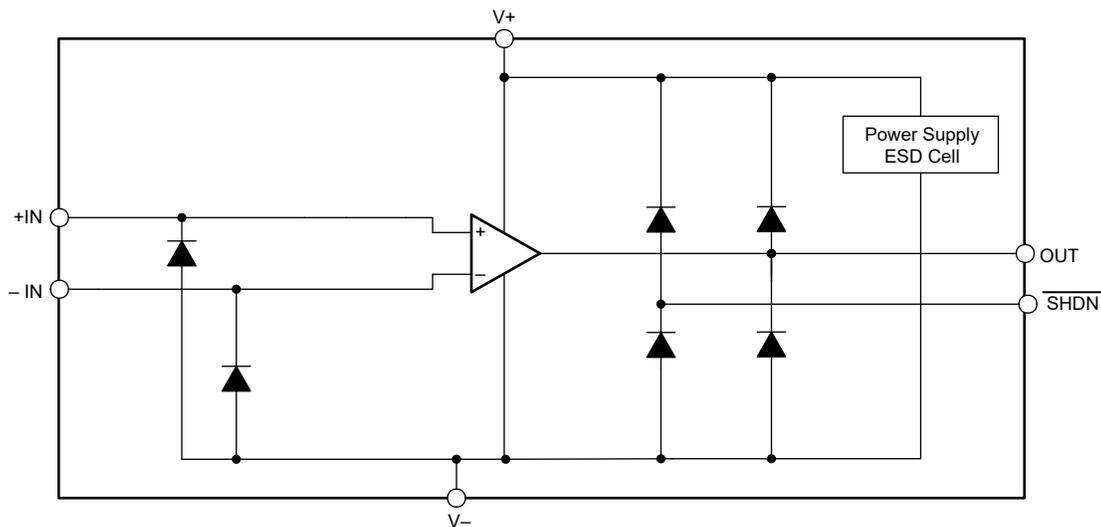
Figure 7-5. Equivalent Internal ESD Circuitry

7.3.9 Input ESD Protection

The OPAx323 family incorporates internal ESD protection circuits on all pins. For inputs, this protection primarily consists of fail safe ESD input structures which feature no current-steering diodes connected between the input and positive power-supply pin as shown in the Figure 7-5. This feature is very useful during power sequencing scenarios where input signal can be present before the positive power supply rail. A fail safe input ESD

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structure prevents any short between inputs and positive power supply. For further details, refer to *Op Amp ESD Protection Structures* application note.

7.3.10 Shutdown Function

The OPAx323S devices feature $\overline{\text{SHDN}}$ pins that disable the op amp, placing the op amp into a low-power standby mode. In this mode, the op amp typically consumes less than 1000nA at room temperature. The $\overline{\text{SHDN}}$ pins are active low, meaning that shutdown mode is enabled when the input to the $\overline{\text{SHDN}}$ pin is a valid logic low.

The $\overline{\text{SHDN}}$ pins are referenced to the negative supply voltage of the op amp. The threshold of the shutdown feature lies around 500mV (typical) and does not change with respect to the supply voltage. Hysteresis has been included in the switching threshold to provide for smooth switching characteristics. For proper shutdown behavior, the $\overline{\text{SHDN}}$ pins must be driven with valid logic signals. A valid logic low is defined as a voltage between V– and (V–) + 0.2V. A valid logic high is defined as a voltage between (V–) + 1V and V+. To enable the amplifier, the $\overline{\text{SHDN}}$ pins must be driven to a valid logic high. To disable the amplifier, the $\overline{\text{SHDN}}$ pins must be driven to a valid logic low. TI highly recommends to not leave the shutdown pin floating, but to connect the shutdown pin to a valid high or low voltage. The maximum voltage allowed at the $\overline{\text{SHDN}}$ pins is (V+) + 0.5V. Exceeding this voltage level damages the device.

The $\overline{\text{SHDN}}$ pins are high-impedance CMOS inputs. Dual op amp versions are independently controlled and quad op amp versions are controlled in pairs with logic inputs. For battery-operated applications, this feature can be used to greatly reduce the average current and extend battery life. The enable and disable time is targeted to be under 1µs for full shutdown of all channels. When disabled, the output assumes a high-impedance state. This architecture allows the OPAx323S to operate as a gated amplifier (or to have the device output multiplexed onto a common analog output bus). Shutdown time (t_{OFF}) depends on loading conditions as any charge on the output capacitor needs to be discharged by any external resistive load or the op-amp. To achieve the 1µs shutdown time, the specified 10kΩ load to midsupply (V_S / 2) is required with no capacitive load.

7.3.11 Packages with an Exposed Thermal Pad

The OPAx323 family is available in packages such as the WQFN-16 (RTE) and WSON-8 (DSG), which feature an exposed thermal pad. Inside the package, the die is attached to this thermal pad using an electrically conductive compound. For this reason, when using a package with an exposed thermal pad, the thermal pad must be connected to V–. Attaching the thermal pad to a potential other then V– is not allowed, and the performance of the device can vary from the *Electrical Characteristics* table when doing so.

7.4 Device Functional Modes

The OPAx323 devices have one functional mode. These devices are powered on as long as the power-supply voltage is between 1.7V (±0.85V) and 5.5V (±2.75V).

The OPAx323S devices feature a shutdown pin, which can be used to place the op amp into a low-power mode. For more information, see the *Shutdown Function* section.

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification. TI does not warrant this information's accuracy or completeness. TI's customers are responsible for determining suitability of components, as well as validating and testing a design's implementation to confirm system functionality.

8.1 Application Information

The OPAx323 family of rail-to-rail input and output operational amplifiers is specifically designed for variety of high gain and high speed applications. These devices operate from 1.7V to 5.5V, are unity-gain stable, and are also an excellent choice for a wide range of general-purpose applications. The output stage is capable of driving small resistive loads connected to any point between V+ and V– as long as the device is not forced into short circuit mode. The input common-mode voltage range includes beyond the rail signal swing and allows the OPAx323 series to be used in many single-supply or dual supply configurations.

8.2 Typical Application

8.2.1 OPAx323 in Low-Side, Current Sensing Application

Figure 8-1 shows the OPA323 configured in a low-side current sensing application.
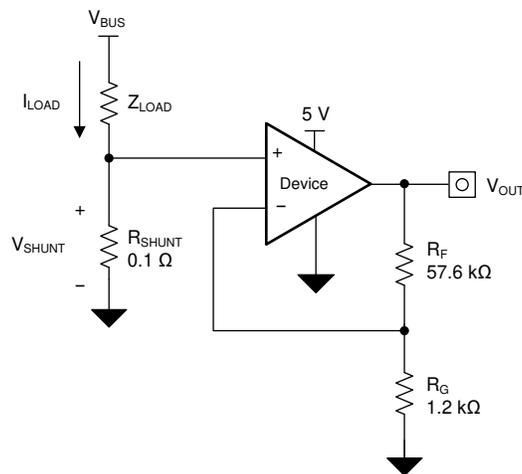
Figure 8-1. OPA323 in a Low-Side, Current-Sensing Application

Product Folder Links: *OPA4323 OPA323 OPA2323*

8.2.1.1 Design Requirements

The design requirements for this design are:
- Load current: 0A to 1A
- Maximum output voltage: 4.9V
- Maximum shunt voltage: 100mV

8.2.1.2 Detailed Design Procedure

The transfer function of the circuit in Figure 8-1 is given in Equation 1.

$$V_{OUT} = I_{LOAD} \times R_{SHUNT} \times Gain \tag{1}$$

The load current (I_{LOAD}) produces a voltage drop across the shunt resistor (R_{SHUNT}). The load current is set from 0A to 1A. To keep the shunt voltage below 100 mV at maximum load current, the largest shunt resistor is defined using Equation 2.

$$R_{SHUNT} = \frac{V_{SHUNT\_MAX}}{I_{LOAD\_MAX}} = \frac{100\ mV}{1\ A} = 100\ m\Omega \tag{2}$$

Using Equation 2, R_{SHUNT} is calculated to be 100mΩ. The voltage drop produced by I_{LOAD} and R_{SHUNT} is amplified by the OPA323 to produce an output voltage of approximately 0V to 4.9V. The gain needed by the OPA323 to produce the necessary output voltage is calculated using Equation 3.

$$Gain = \frac{V_{OUT\_MAX} - V_{OUT\_MIN}}{V_{IN\_MAX} - V_{IN\_MIN}} \tag{3}$$

Using Equation 3, the required gain is calculated to be 49V/V, which is set with resistors R_F and R_G. Equation 4 sizes the resistors R_F and R_G, to set the gain of the OPA323 to 49V/V.

$$Gain = 1 + \frac{R_F}{R_G} \tag{4}$$

Selecting R_F as 57.6kΩ and R_G as 1.2kΩ provides a combination that equals 49V/V. Figure 8-2 shows the measured transfer function of the circuit shown in Figure 8-1. Notice that the gain is only a function of the feedback and gain resistors. This gain is adjusted by varying the ratio of the resistors and the actual resistors values are determined by the impedance levels that the designer wants to establish. The impedance level determines the current drain, the effect that stray capacitance has, and a few other behaviors. There is no impedance selection that works for every system; choose an impedance that is best for the system parameters.

8.2.1.3 Application Curve
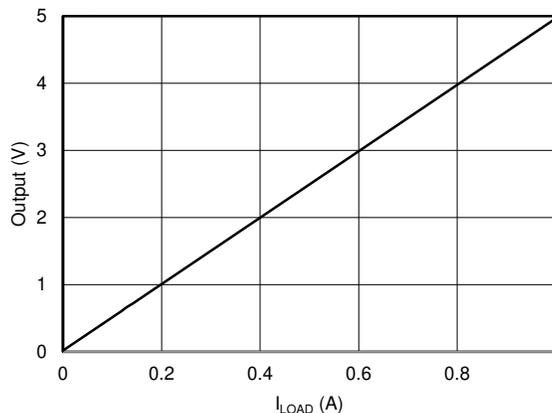
Figure 8-2. Low-Side, Current-Sense Transfer Function

Product Folder Links: *OPA4323 OPA323 OPA2323*

8.3 Power Supply Recommendations

The OPAx323 is tested for amplifier operation at 1.7V and is fully specified from 1.8V to 5.5V (±0.9V to ±2.75V); many specifications apply from –40°C to 125°C. *Electrical Characteristics* presents parameters that can exhibit significant variance regarding operating voltage or temperature.

CAUTION
Supply voltages larger than 7V can permanently damage the device; for more information, see the *Absolute Maximum Ratings* table.

TI highly recommends to add low-ESR ceramic bypass capacitors (C_{BYP}) between each supply pin and ground. Only one C_{BYP} is sufficient for single supply operation. Place the C_{BYP} as close to the device as possible to reduce coupling errors from noisy or high-impedance power supplies. Make sure the power supply trace routes through C_{BYP} before reaching the amplifier power supply terminals. For more information, see *Layout Guidelines*.

8.4 Layout

8.4.1 Layout Guidelines

For best operational performance, use good printed circuit board (PCB) layout practices, including:

- Noise can propagate into analog circuitry through the power connections of the board and propagate to the power pins of the op amp. Bypass capacitors are used to reduce the coupled noise by providing a low-impedance path to ground.
  - Connect low-ESR, 0.1µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. One bypass capacitor from V+ to ground is adequate for single-supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces electromagnetic interference (EMI) noise pickup. Take care to physically separate digital and analog grounds, paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, then cross the sensitive trace at a 90 degree angle, which is much better as opposed to running the traces in parallel with the noisy trace.
- Place the external components as close to the device as possible, as shown in *Layout Example*. Keeping R_1 and R_2 close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- TI recommends cleaning the PCB following board assembly for best performance.
- Any precision integrated circuit can experience performance shifts resulting from moisture ingress into the plastic package. Following any aqueous PCB cleaning process, TI recommends baking the PCB assembly to remove moisture introduced into the device packaging during the cleaning process. A low-temperature, post-cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

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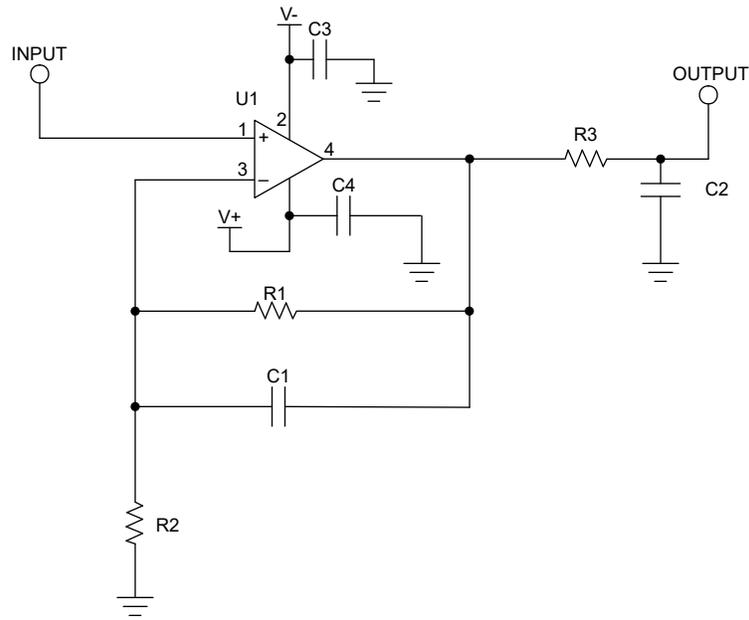
8.4.2 Layout Example

Note: C3 and C4 are C_{BYP} capacitors

Figure 8-3. Schematic for Noninverting Configuration Layout Example
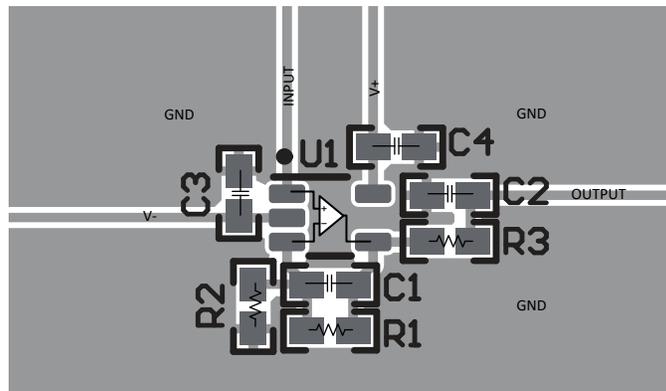
Figure 8-4. Operational Amplifier Board Layout for Noninverting Configuration - SC70 (DCK) Package

9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation see the following:
- Texas Instruments, *QFN/SON PCB Attachment* application note
- Texas Instruments, *Quad Flatpack No-Lead Logic Packages* application note

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.4 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary   This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA2323IDDFR	Active	Production	SOT-23-THIN (DDF) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	23DDF
OPA2323IDDFR.A	Active	Production	SOT-23-THIN (DDF) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	23DDF
OPA2323IDGKR	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2DGK
OPA2323IDGKR.A	Active	Production	VSSOP (DGK) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2DGK
OPA2323IDR	Active	Production	SOIC (D) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2323ID
OPA2323IDR.A	Active	Production	SOIC (D) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2323ID
OPA323IDCKR	Active	Production	SC70 (DCK) | 5	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1RG
OPA323IDCKR.A	Active	Production	SC70 (DCK) | 5	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1RG
OPA4323IDYYR	Active	Production	SOT-23-THIN (DYY) | 14	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	125 to -40	O4323IDYYR
OPA4323IDYYR.A	Active	Production	SOT-23-THIN (DYY) | 14	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	125 to -40	O4323IDYYR
OPA4323IPWR	Active	Production	TSSOP (PW) | 14	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	125 to -40	O4323PW
OPA4323IPWR.A	Active	Production	TSSOP (PW) | 14	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	125 to -40	O4323PW

(1) Status: For more details on status, see our product life cycle.

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers
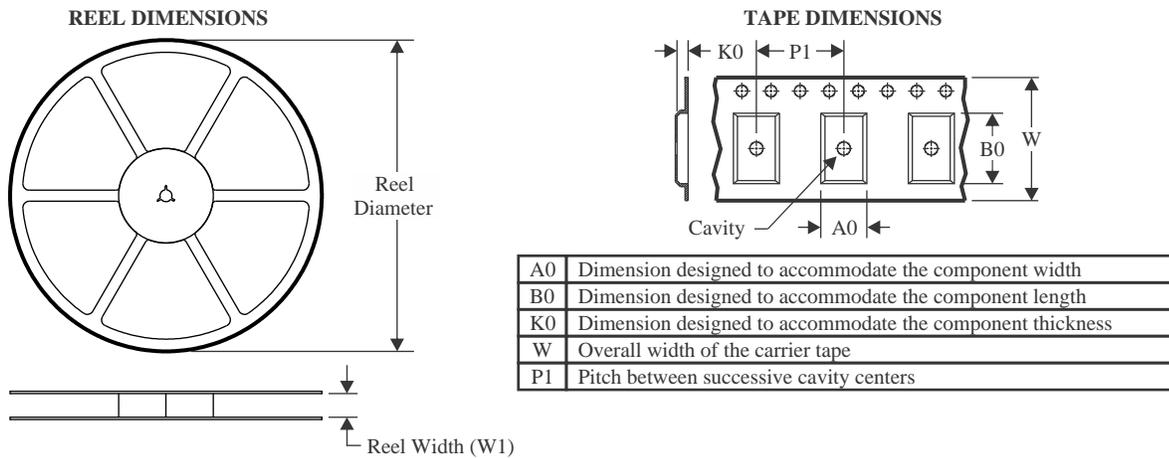
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
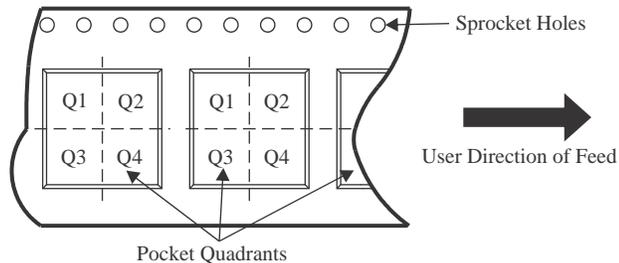
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2323IDDFR	SOT-23-THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA2323IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2323IDR	SOIC	D	8	3000	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA323IDCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
OPA4323IDYYR	SOT-23-THIN	DYY	14	3000	330.0	12.4	4.8	3.6	1.6	8.0	12.0	Q3
OPA4323IPWR	TSSOP	PW	14	3000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS
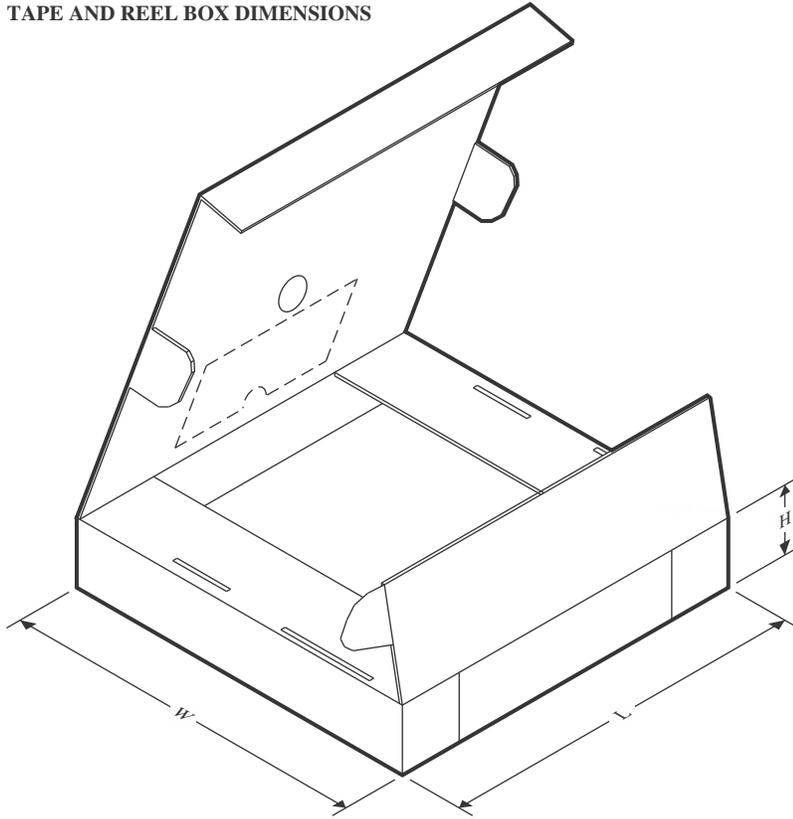
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2323IDDFR	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
OPA2323IDGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
OPA2323IDR	SOIC	D	8	3000	353.0	353.0	32.0
OPA323IDCKR	SC70	DCK	5	3000	190.0	190.0	30.0
OPA4323IDYYR	SOT-23-THIN	DYY	14	3000	336.6	336.6	31.8
OPA4323IPWR	TSSOP	PW	14	3000	353.0	353.0	32.0
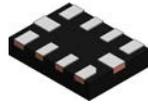
B | 1.6 / 1.4 | A

PIN 1 INDEX AREA

2.1 / 1.9

0.1 MIN
SIDE WALL
WETTABLE FLANK

OPTIONAL: SIDE WALL PIN DETAIL
NOTE 3

0.40 / 0.34

C

SEATING PLANE

0.05 / 0.00

⌓ | 0.05 | C

2X 0.35 / 0.25

⊕ | 0.1 Ⓜ | C | A | B
0.05 Ⓜ | C

SYMM ℄

5

4

6

4X 0.3 / 0.2

⊕ | 0.1 Ⓜ | C | A | B
0.05 Ⓜ | C

(0.127) TYP

2X 1.5

SYMM ℄

6X 0.5

4X 0.25 / 0.15

⊕ | 0.1 Ⓜ | C | A | B
0.05 Ⓜ | C

1

9

10

PIN 1 ID
(45° X 0.1)

10X 0.45 / 0.35

4220582/B 05/2025
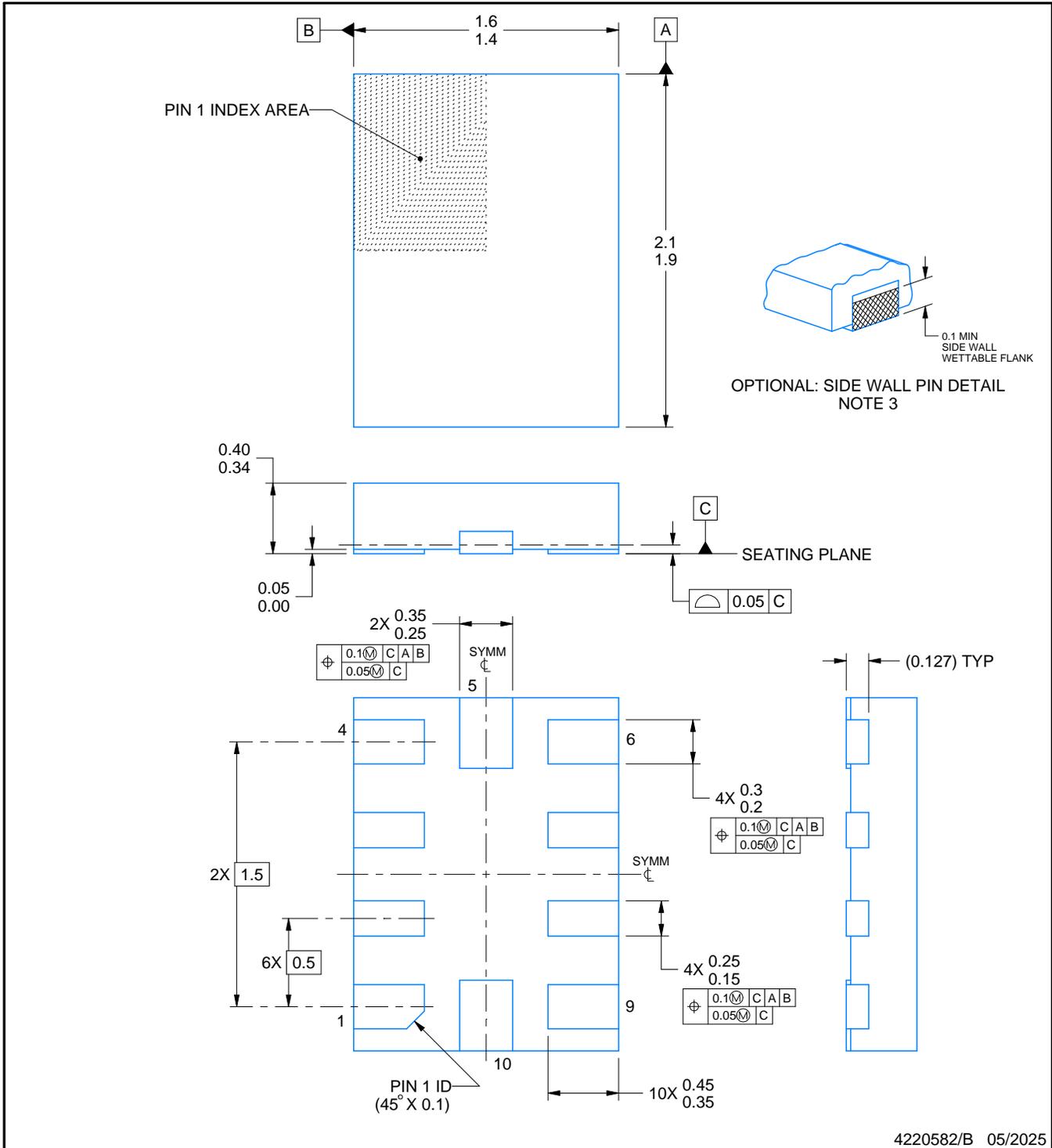
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing
   per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Minimum 0.1 mm solder wetting on pin side wall. Available for wettable flank version only.

TEXAS
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2X (0.3)

SYMM
℄

10

SEE SOLDER MASK
DETAIL

10X (0.6)

4X (0.25)

1

9

4X (0.2)

6X (0.5)

SYMM
℄

(1.8)

(R0.05) TYP

4

6

5

(1.3)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 35X

0.05 MAX
ALL AROUND

METAL EDGE

EXPOSED METAL

SOLDER MASK
OPENING

NON SOLDER MASK
DEFINED
(PREFERRED)

0.05 MIN
ALL AROUND

METAL UNDER
SOLDER MASK

EXPOSED
METAL

SOLDER MASK
OPENING

SOLDER MASK DEFINED

SOLDER MASK DETAILS
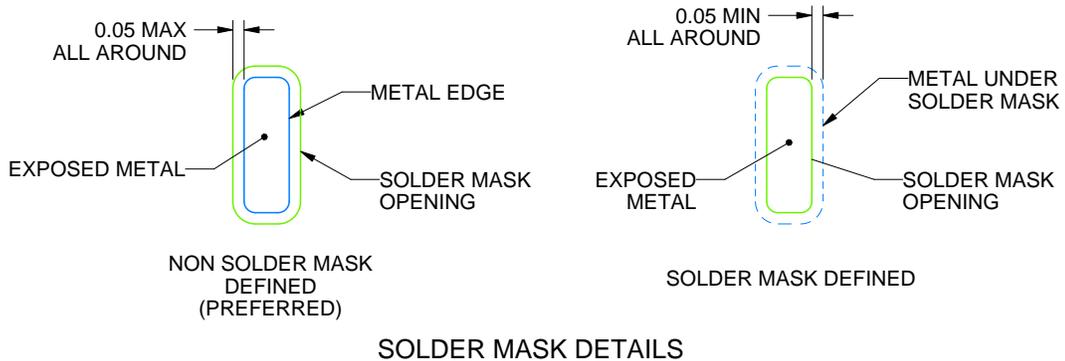
4220582/B   05/2025

NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

2X (0.3)

SYMM

10

10X (0.6)

4X (0.25)

1

9

4X (0.2)

6X (0.5)

(R0.05) TYP

SYMM

(1.8)

4

6

5

(1.3)
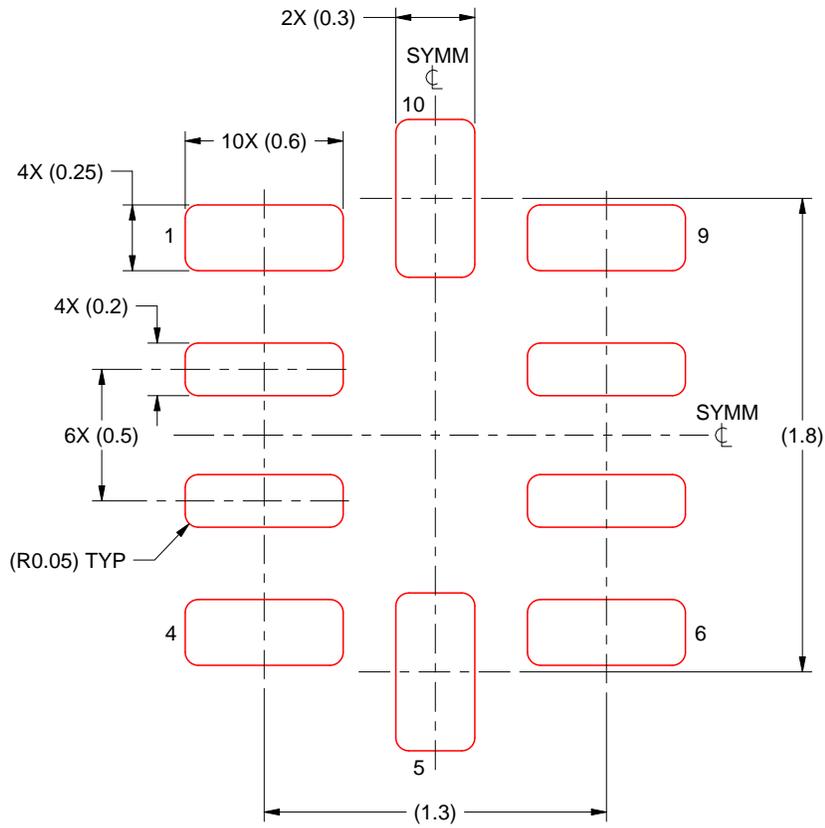
SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 35X

4220582/B 05/2025

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
   design recommendations.

PIN 1
INDEX AREA

3.0
2.6

1.75
1.45

B

A

1

6

2X 0.95

1.9

3.05
2.75

2

5

3

4

6X 0.50
0.25

⊕ 0.2 Ⓜ C A B

C

△ 0.1 C

4X 0°-15°

(1.1)

1.45
0.90

0.15 TYP
0.00

0.22 TYP
0.08

4X 4°-15°

0.25

GAGE PLANE

8° TYP
0°

0.6 TYP
0.3

SEATING PLANE
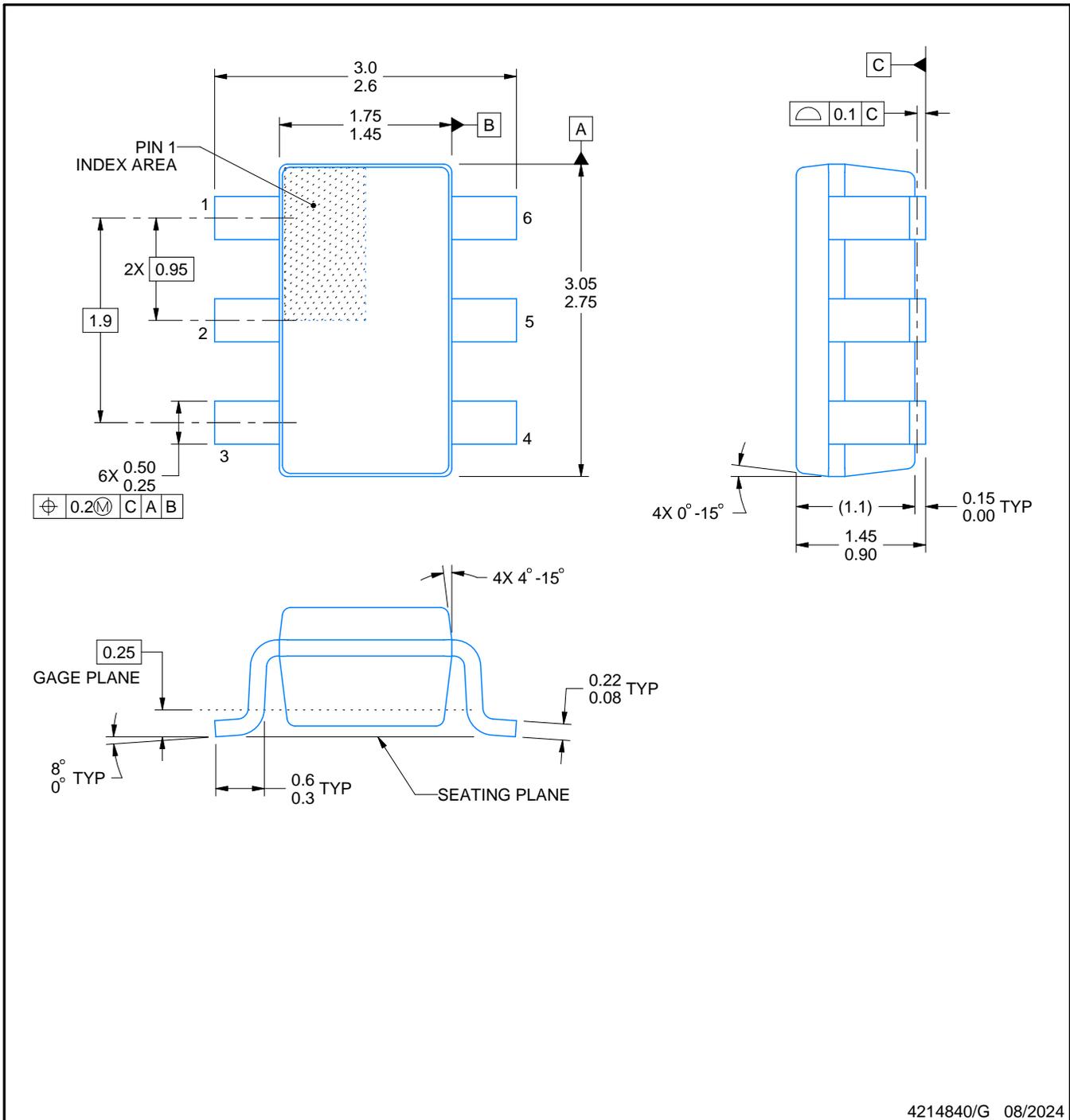
4214840/G 08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Refernce JEDEC MO-178.

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6X (1.1)

PKG ℄

1

6X (0.6)

6

2

SYMM ℄

5

2X (0.95)

3

4

(R0.05) TYP

(2.6)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.07 MAX
ARROUND

NON SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.07 MIN
ARROUND

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214840/G   08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

PKG

6X (1.1)

1

6X (0.6)

6

2

SYMM

5

2X(0.95)

3

4

(R0.05) TYP

(2.6)
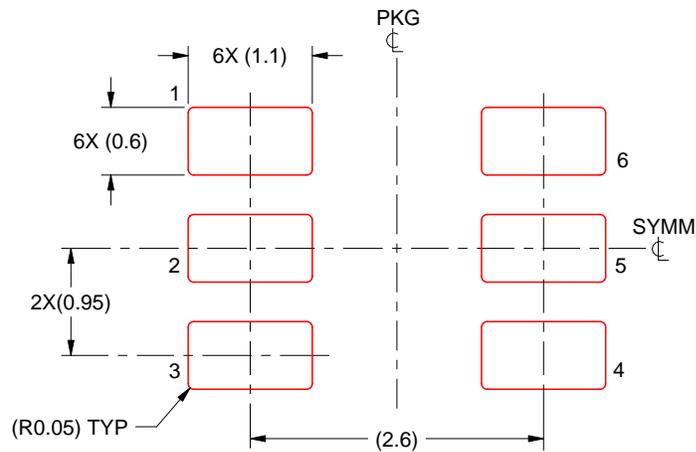
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

6.6
6.2 TYP

A

PIN 1 INDEX AREA

1

12X 0.65

14

5.1
4.9
NOTE 3

2X

3.9

7

8

B

4.5
4.3
NOTE 4

14X 0.30
0.17

⊕ 0.1 Ⓜ C A B

SEATING
PLANE

C

◻ 0.1 C

4X (0° -12°)

1.2 MAX

SEE DETAIL A

(0.15) TYP

0.25
GAGE PLANE

0.15
0.05

0.75
0.50

0° -8°

DETAIL A
TYPICAL

4220202/B   12/2023

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

14X (1.5)

SYMM

1

14X (0.45)

(R0.05) TYP

14

SYMM

12X (0.65)

7

8

(5.8)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

SOLDER MASK OPENING

METAL

METAL UNDER SOLDER MASK

SOLDER MASK OPENING

EXPOSED METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK DETAILS

SOLDER MASK
DEFINED

4220202/B   12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

14X (1.5)

SYMM

1

14X (0.45)

(R0.05) TYP

14

SYMM

12X (0.65)

7

8

(5.8)
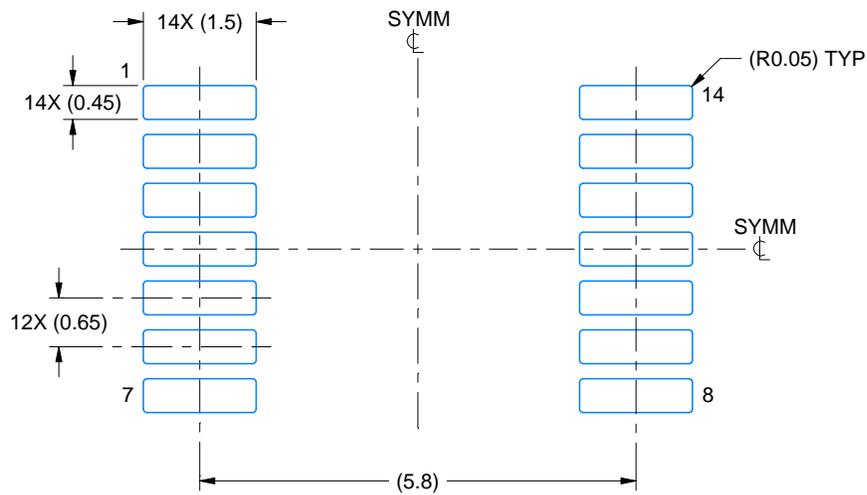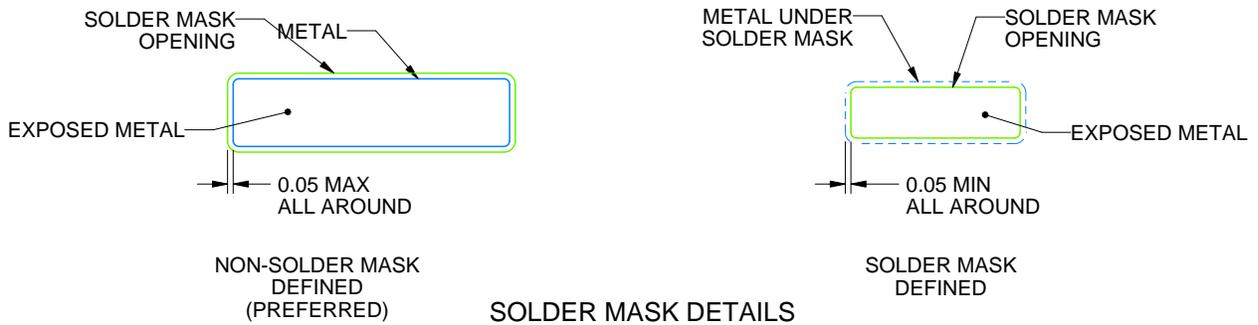
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B   12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

5.05 / 4.75 TYP

A

PIN 1 INDEX AREA

C

0.1 C

SEATING PLANE

8

6X 0.65

2X 1.95

1

3.1 / 2.9 NOTE 3

4

5

8X 0.38 / 0.25

⊕ 0.13 Ⓜ C A B

B

3.1 / 2.9 NOTE 4

0.23 / 0.13

SEE DETAIL A

0.25 GAGE PLANE

1.1 MAX

0° -8°

0.7 / 0.4

0.15 / 0.05

DETAIL A
TYPICAL
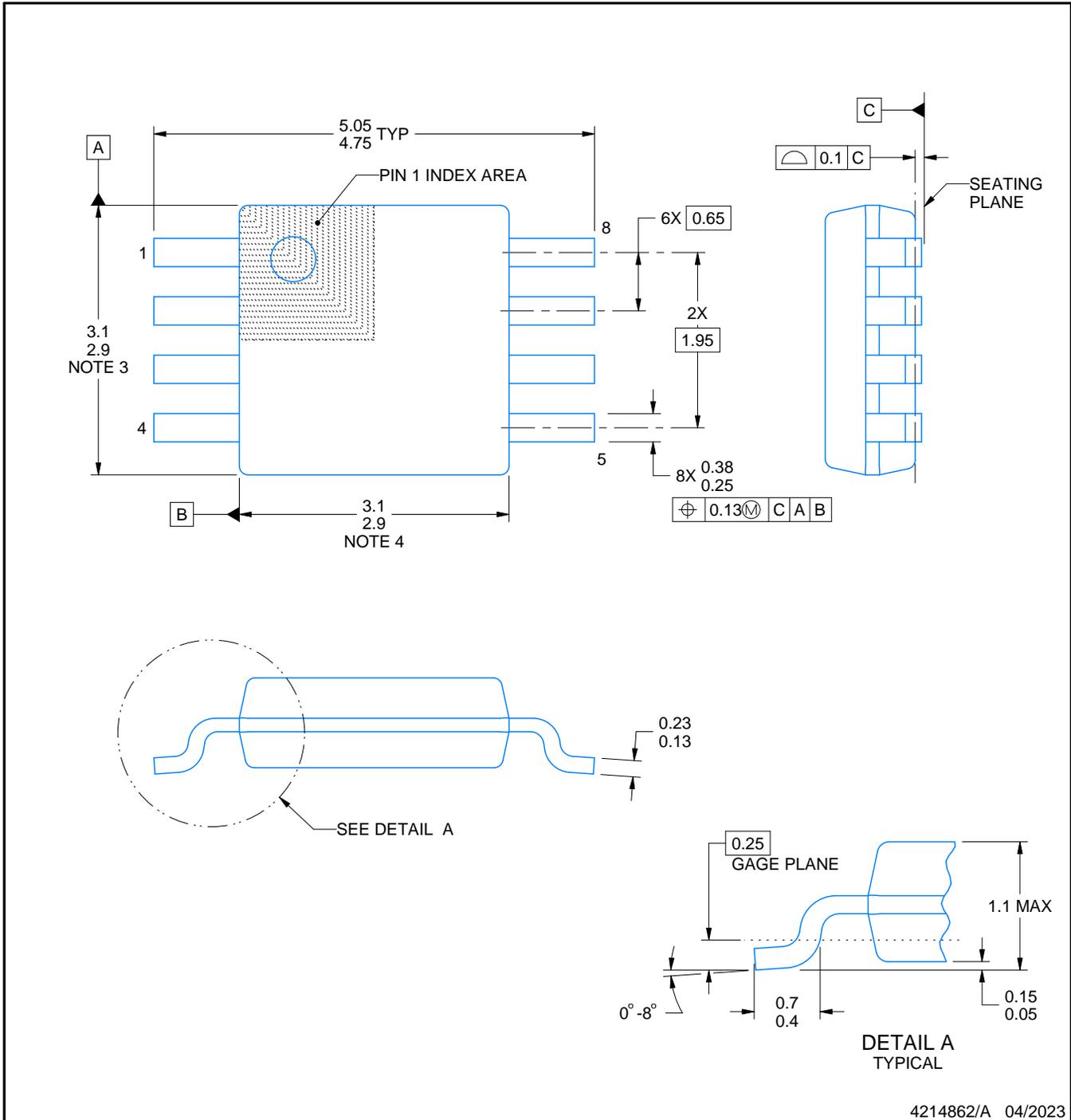
4214862/A   04/2023

PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

DGK0008A

8X (1.4)

8X (0.45)   1

6X (0.65)

4

SYMM

(R0.05) TYP

8

SYMM

5

SEE DETAILS

(4.4)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.05 MIN
ALL AROUND
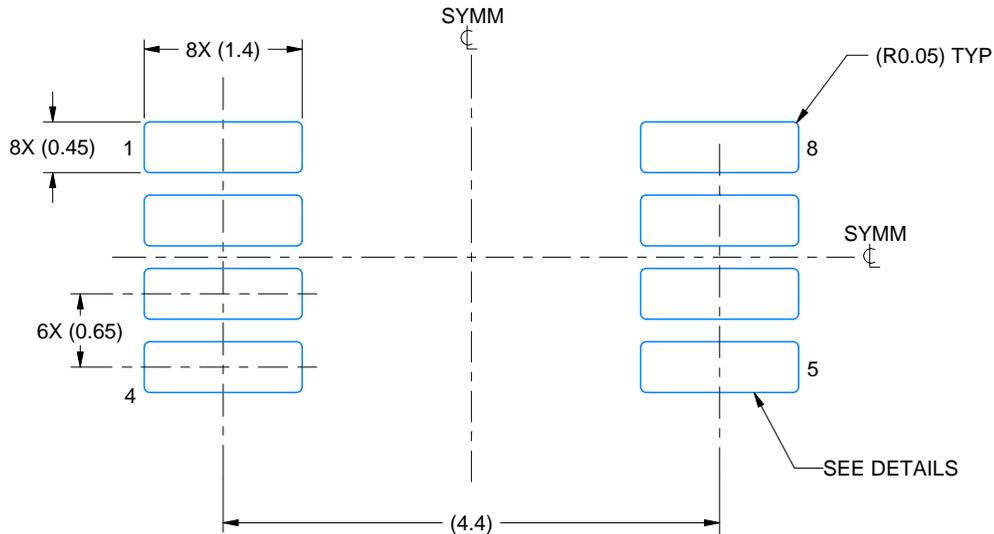
SOLDER MASK
DEFINED
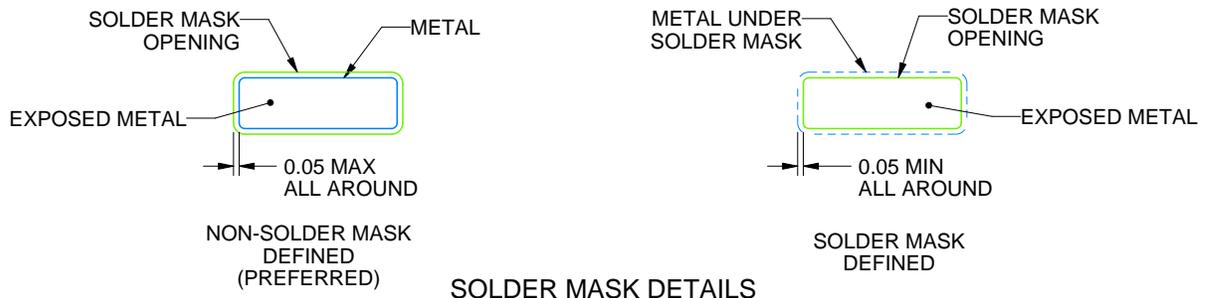
SOLDER MASK DETAILS

4214862/A   04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown
   on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.
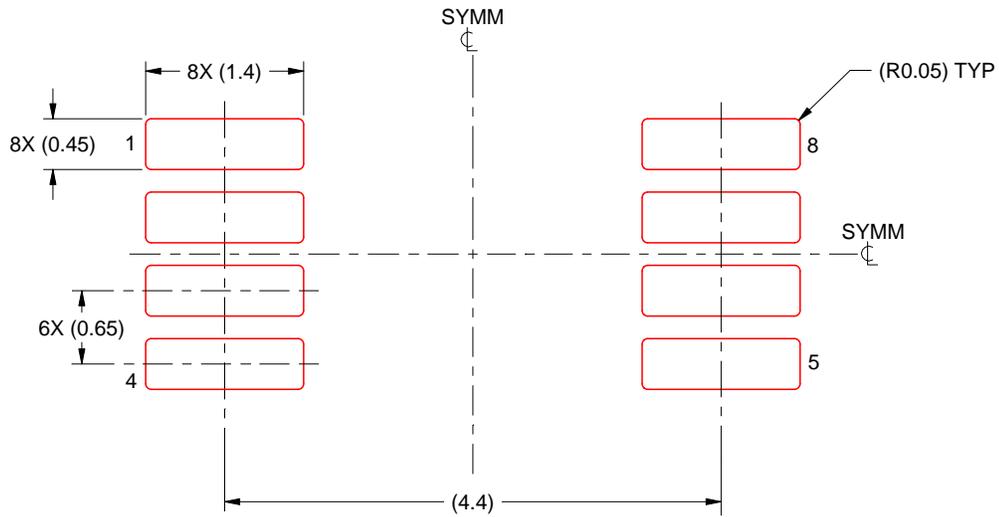
SOLDER PASTE EXAMPLE
SCALE: 15X

SYMM

8X (1.4)

8X (0.45)   1

(R0.05) TYP

8

SYMM

6X (0.65)

4

5

(4.4)

4214862/A   04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4225944/A

PLASTIC SMALL OUTLINE

3.36
3.16

A

PIN 1 INDEX AREA

12X 0.5

14

1

4.3
4.1
NOTE 3

2X
3

7

8

B

2.1
1.9

14X 0.3
0.11

⊕ 0.1 Ⓜ C A B

SEATING PLANE

C

⌒ 0.1 C

4X 0° - 15°

1.1 MAX

4X 4° - 15°

0.2
0.08 TYP

SEE DETAIL A

0.25
GAUGE PLANE

0°- 8°

0.63
0.33

0.1
0.0

DETAIL A
TYP
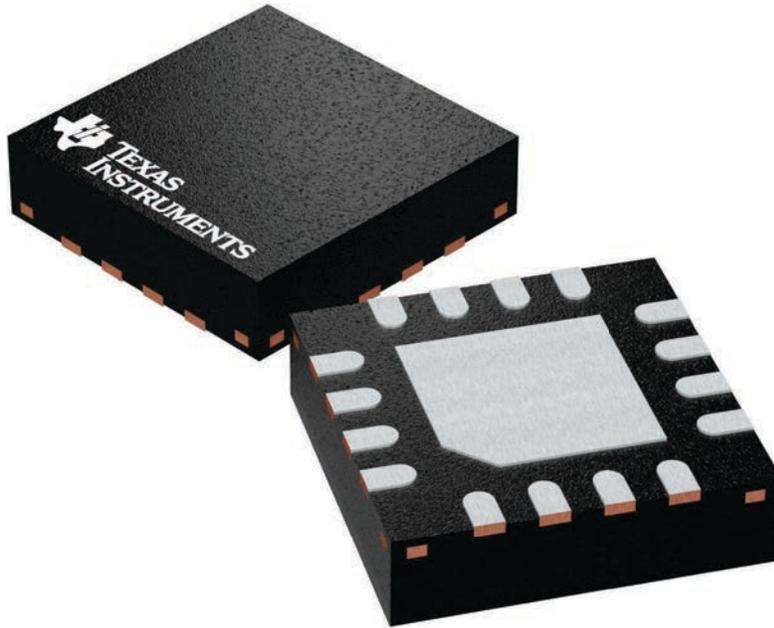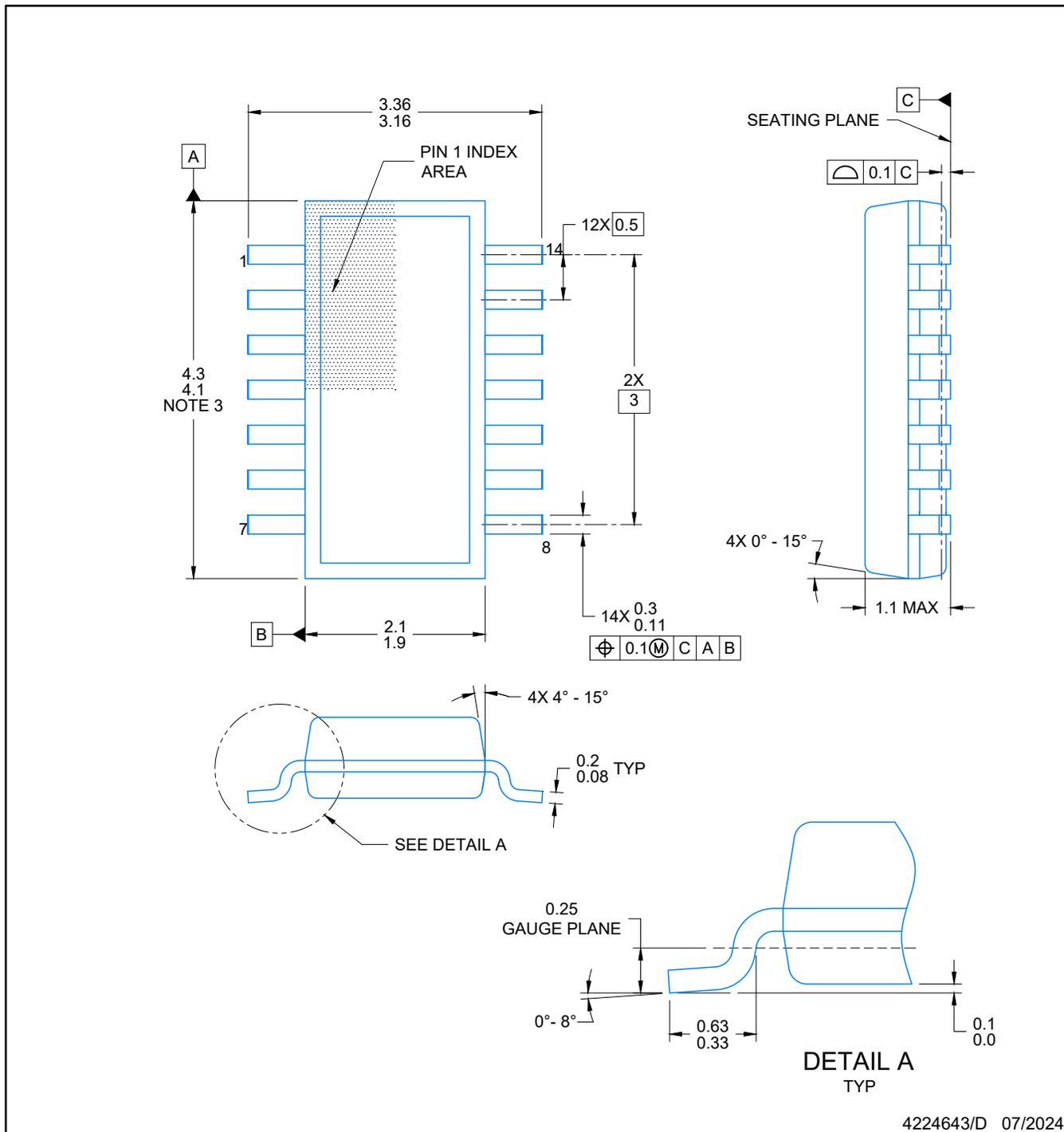
4224643/D   07/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
5. Reference JEDEC Registration MO-345, Variation AB
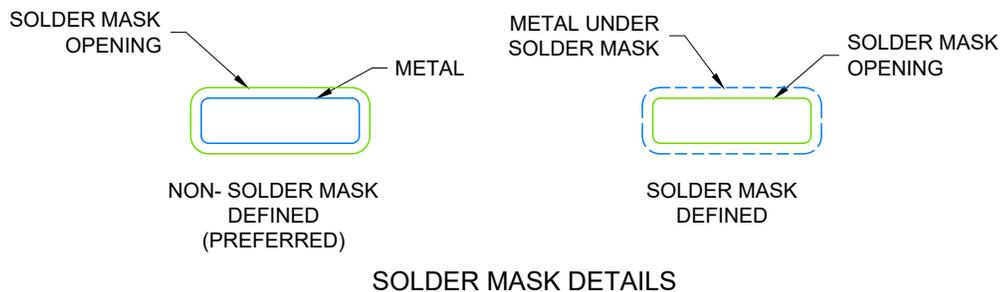
PLASTIC SMALL OUTLINE

SYMM
℄

14X (1.05)

1

14

14X (0.3)

SYMM
℄

12X (0.5)

7

8

(R0.05) TYP

(3)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

NON- SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4224643/D   07/2024

NOTES: (continued)

6.   Publication IPC-7351 may have alternate designs.
7.   Solder mask tolerances between and around signal pads can vary based on board fabrication site.

TEXAS
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SYMM
₵

14X (1.05)

1

14

14X (0.3)

SYMM
₵

12X (0.5)

7

8

(R0.05) TYP

(3)

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 20X

4224643/D   07/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE
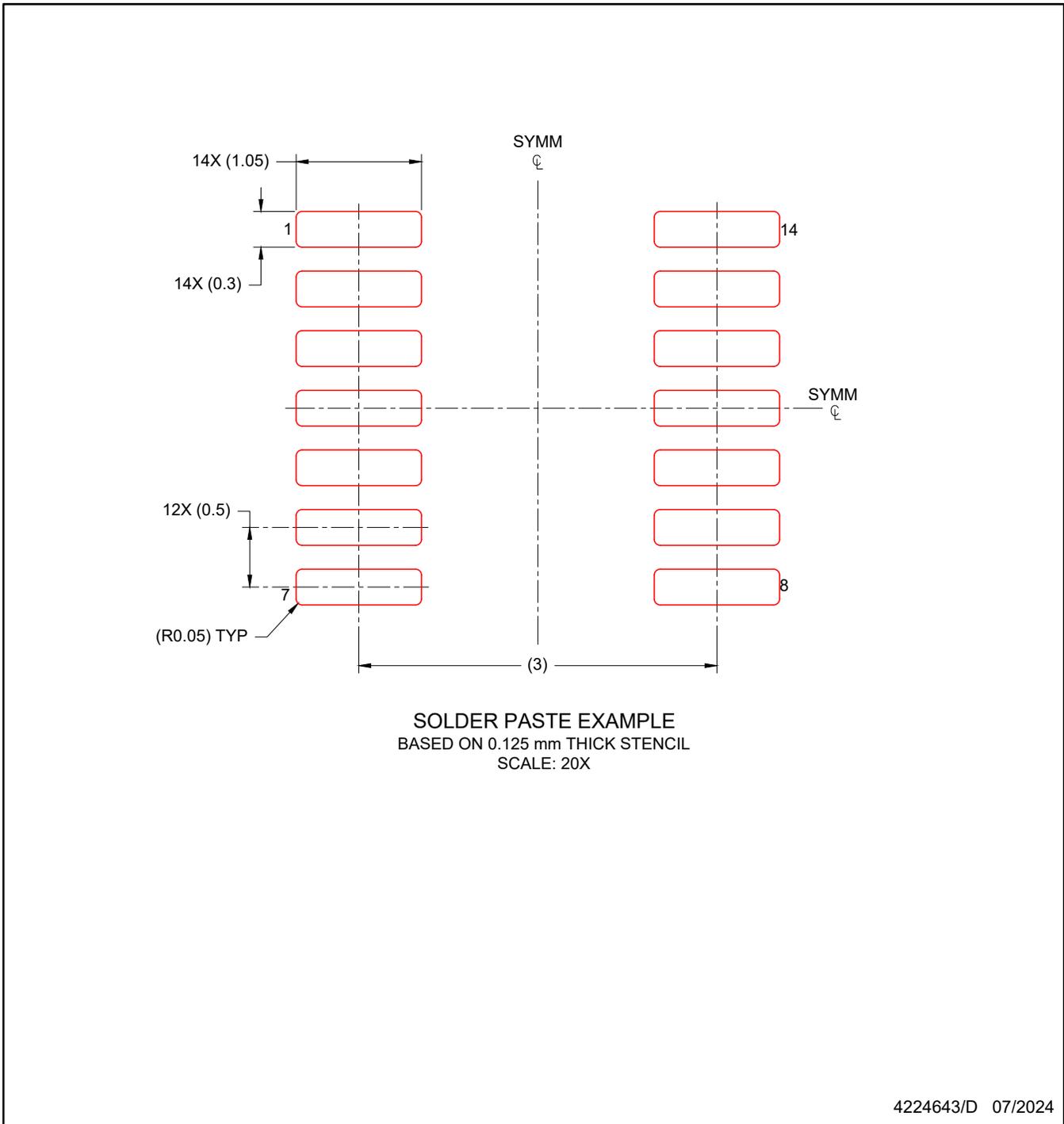
DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR

4214834/G   11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

TEXAS INSTRUMENTS
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5X (0.95)

PKG ₵

1

5X (0.4)

2

2X (0.65)

3

(R0.05) TYP

5

SYMM ₵

(1.3)

(2.2)

4

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

SOLDER MASK OPENING

METAL

EXPOSED METAL

0.07 MAX ARROUND

NON SOLDER MASK DEFINED (PREFERRED)

METAL UNDER SOLDER MASK

SOLDER MASK OPENING

EXPOSED METAL

0.07 MIN ARROUND

SOLDER MASK DEFINED

SOLDER MASK DETAILS

4214834/G   11/2024

NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

PKG
℄

5X (0.95)

1

5X (0.4)

5

2

SYMM
℄

(1.3)

2X(0.65)

3

4

(R0.05) TYP

(2.2)

SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214834/G   11/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.

2.95 / 2.65 TYP

PIN 1 ID AREA

A

1

2.95 / 2.85 NOTE 3

4

5

8

6X 0.65

2X 1.95

8X 0.38 / 0.22

⊕ 0.1 Ⓜ C A B

B 1.65 / 1.55

C

SEATING PLANE

⌒ 0.1 C

4X 0°-15°

1.1 MAX

4X 4°-15°

0.20 / 0.08 TYP

SEE DETAIL A

GAGE PLANE 0.25

0°-8°

0.6 / 0.3

0.1 / 0.0

DETAIL A TYPICAL

4222047/E 07/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.

8X (1.05)

SYMM

1

8X (0.45)

8

SYMM

6X (0.65)

4

5

(R0.05)
TYP

(2.6)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

SOLDER MASK
OPENING

METAL

0.05 MAX
ALL AROUND

EXPOSED
METAL

**NON SOLDER MASK
DEFINED**

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

0.05 MIN
ALL AROUND
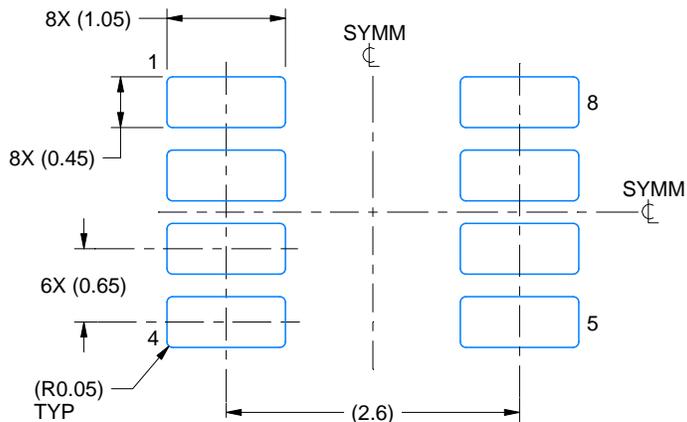
EXPOSED
METAL

**SOLDER MASK
DEFINED**

SOLDER MASK DETAILS

4222047/E   07/2024

NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8X (1.05)

SYMM

(R0.05) TYP

1

8X (0.45)

8

SYMM

6X (0.65)

4

5

(2.6)
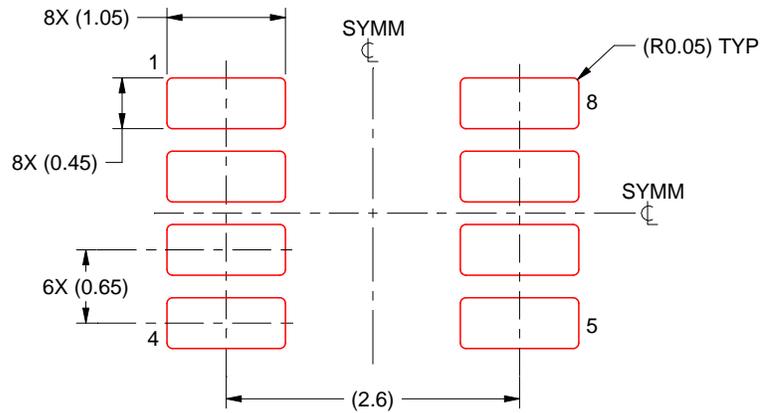
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4222047/E   07/2024

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.
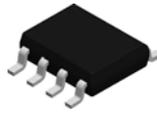
.228-.244   TYP
[5.80-6.19]

PIN 1 ID AREA

A

1

8

6X .050
[1.27]

.189-.197
[4.81-5.00]
NOTE 3

2X
.150
[3.81]

4

5

B

.150-.157
[3.81-3.98]
NOTE 4

8X .012-.020
[0.31-0.51]

⊕ .010 [0.25] Ⓜ C A B

C

SEATING PLANE

⌒ .004 [0.1] C

4X (0°-15°)

.069 MAX
[1.75]

SEE DETAIL A

4X (0°-15°)

.005-.010   TYP
[0.13-0.25]

.010
[0.25]

0° - 8°

.016-.050
[0.41-1.27]

(.041)
[1.04]

.004-.010
[0.11-0.25]

DETAIL A
TYPICAL
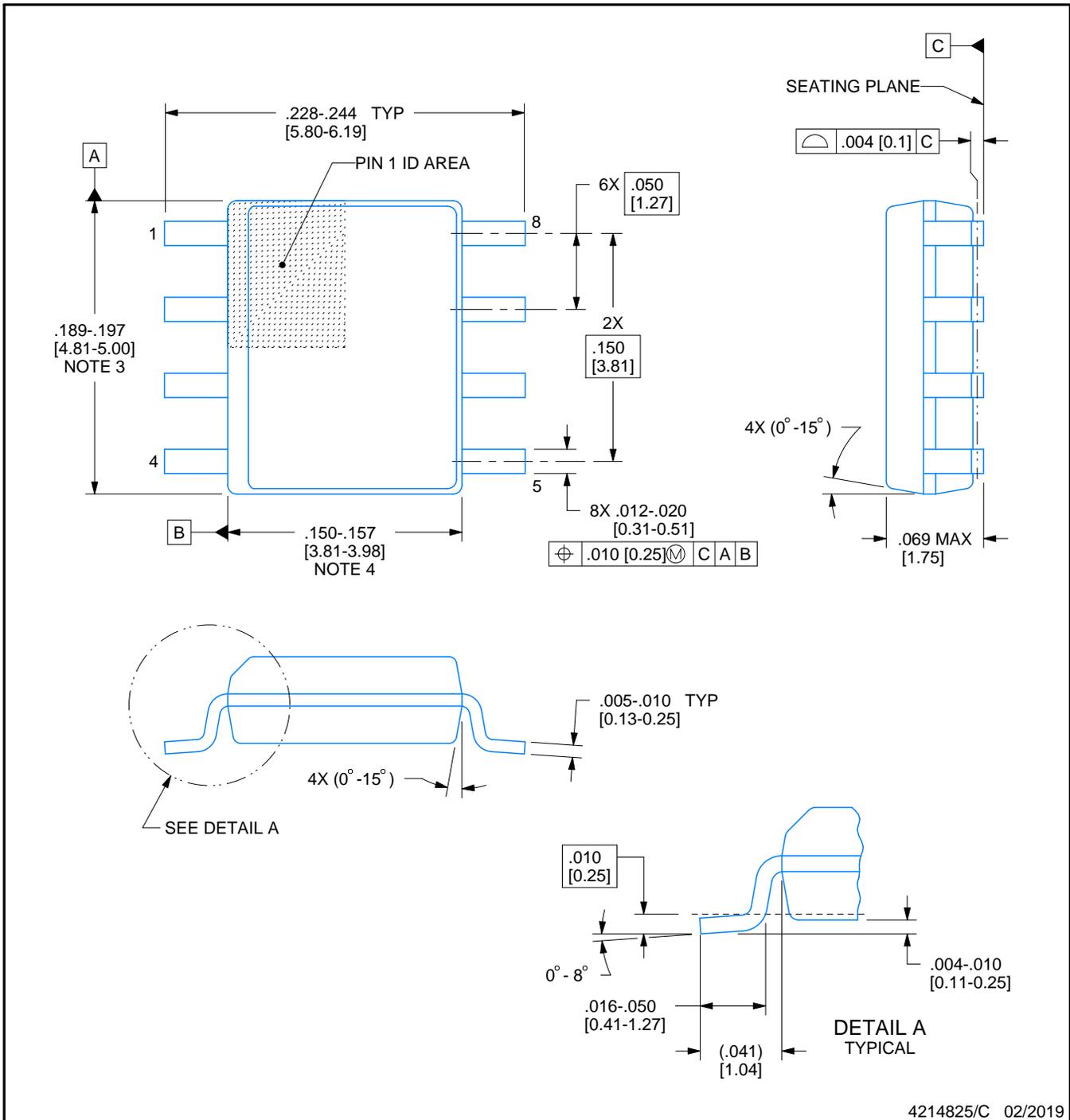
4214825/C   02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches.
   Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
   exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

8X (.061)
[1.55]

SYMM

SEE
DETAILS

1

8

8X (.024)
[0.6]

SYMM

(R.002) TYP
[0.05]

4

5

6X (.050)
[1.27]

(.213)
[5.4]

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X

METAL

SOLDER MASK
OPENING

SOLDER MASK
OPENING

METAL UNDER
SOLDER MASK

EXPOSED
METAL

EXPOSED
METAL

.0028 MAX
[0.07]
ALL AROUND

.0028 MIN
[0.07]
ALL AROUND
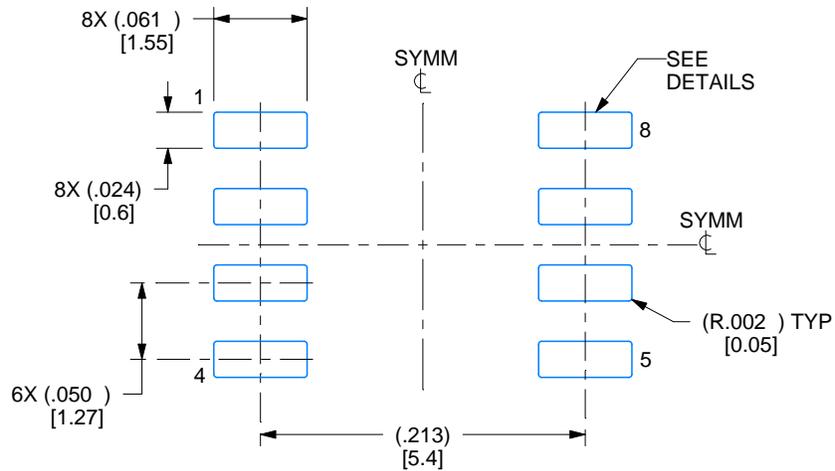
NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED
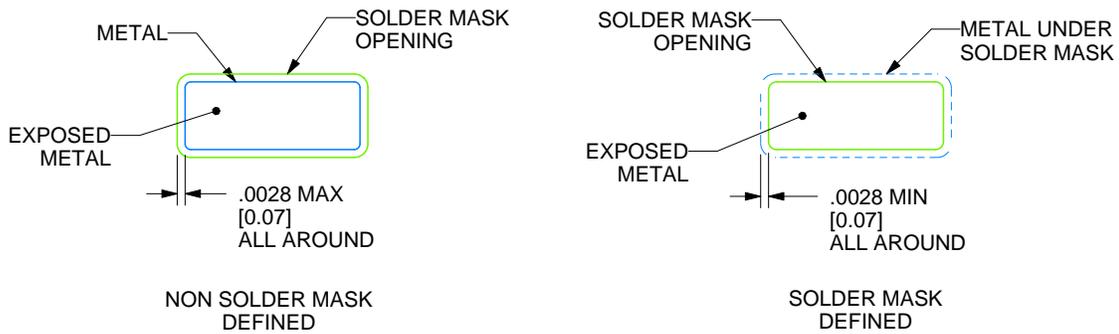
SOLDER MASK DETAILS

4214825/C   02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8X (.061)
[1.55]

SYMM

1

8X (.024)
[0.6]

SYMM

8

(R.002) TYP
[0.05]

5

4

6X (.050)
[1.27]

(.213)
[5.4]
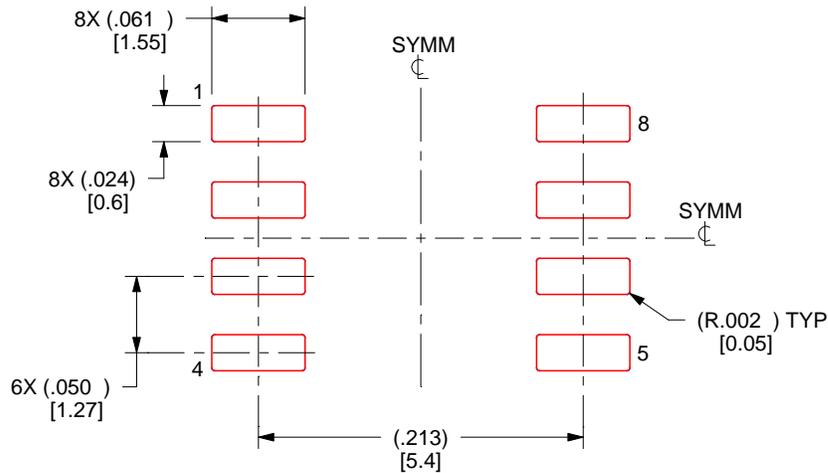
SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C   02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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